



# 存储层次

100076202: 计算机系统导论

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# 提纲

- **内存抽象** The memory abstraction
- **随机访问存储器：主存构建块** RAM : main memory building block
- **引用的局部性** Locality of reference
- **存储器层次结构** The memory hierarchy
- **存储技术和趋势** Storage technologies and trends

# 写和读内存 Writing & Reading Memory



## ■ 写 Write

- 从CPU向内存传送数据 Transfer data from CPU to memory  
`movq %rax, 8(%rsp)`
- “存储” 操作 “Store” operation

## ■ 读 Read

- 从内存向CPU传送数据 Transfer data from memory to CPU  
`movq 8(%rsp), %rax`
- “装载” 操作 “Load” operation

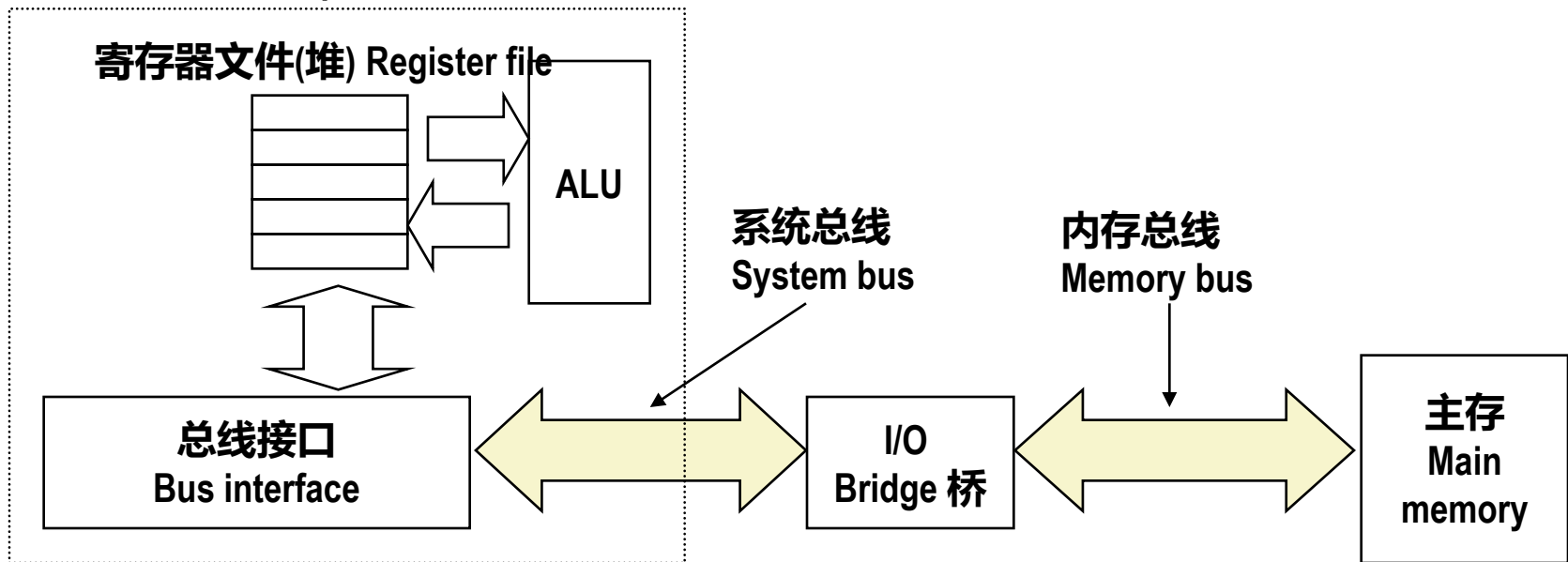
# 传统（2008之前）CPU和内存之间的互连总线结构

## Traditional (pre-2008) Bus Structure Connecting CPU and Memory



- **总线**是一组并行的用于传输地址、数据和控制信号的导线 A **bus** is a collection of parallel wires that carry address, data, and control signals.
- **总线通常是多个设备共享的** Buses are typically shared by multiple devices.

CPU芯片 CPU chip

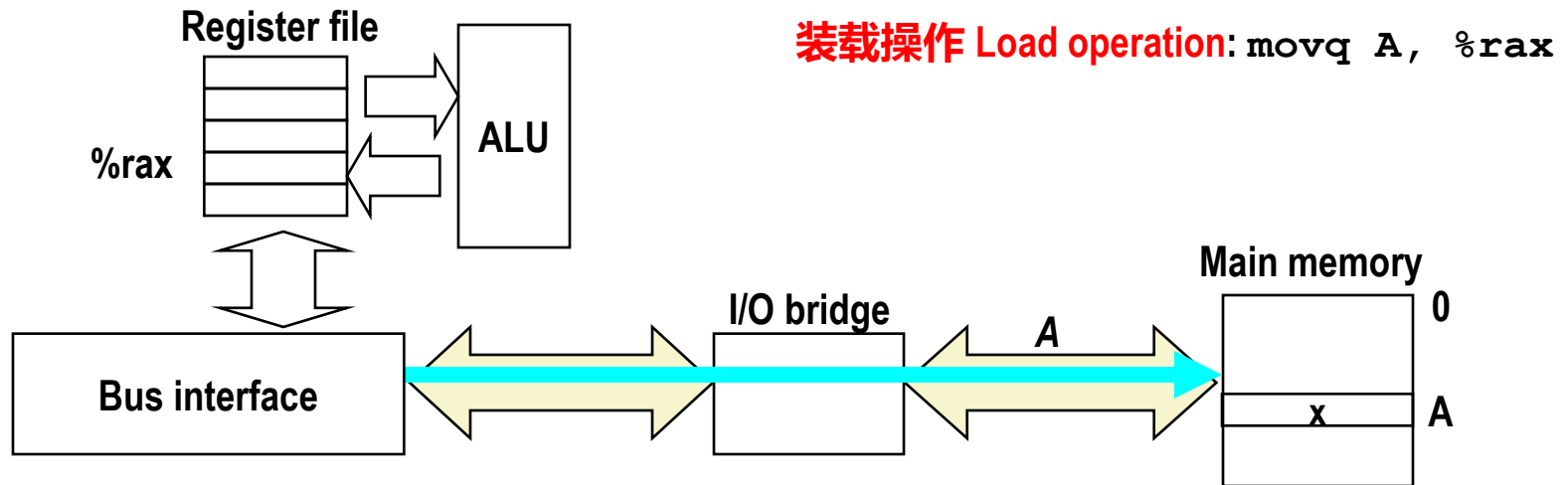




# 内存读事务 (1)

## Memory Read Transaction (1)

- CPU将地址A放到内存总线上 CPU places address A on the memory bus.

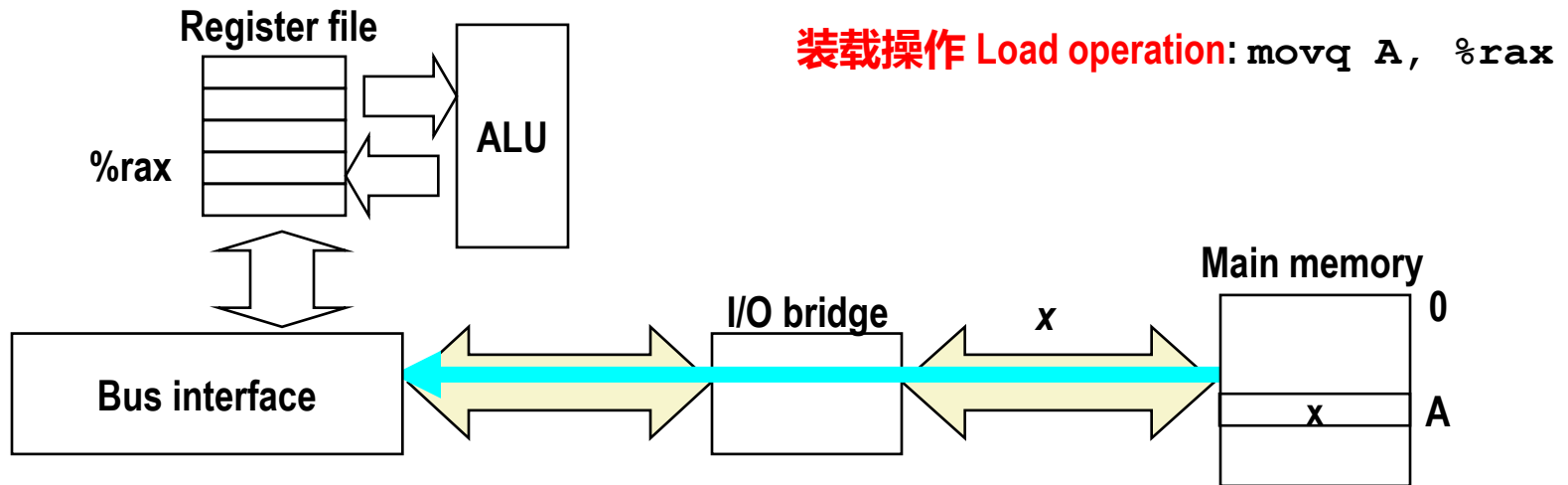




# 内存读事务 (2)

## Memory Read Transaction (2)

- 主存从内存总线获得地址A，读取对应的字x，并将其放置到总线上 Main memory reads A from the memory bus, retrieves word x, and places it on the bus.

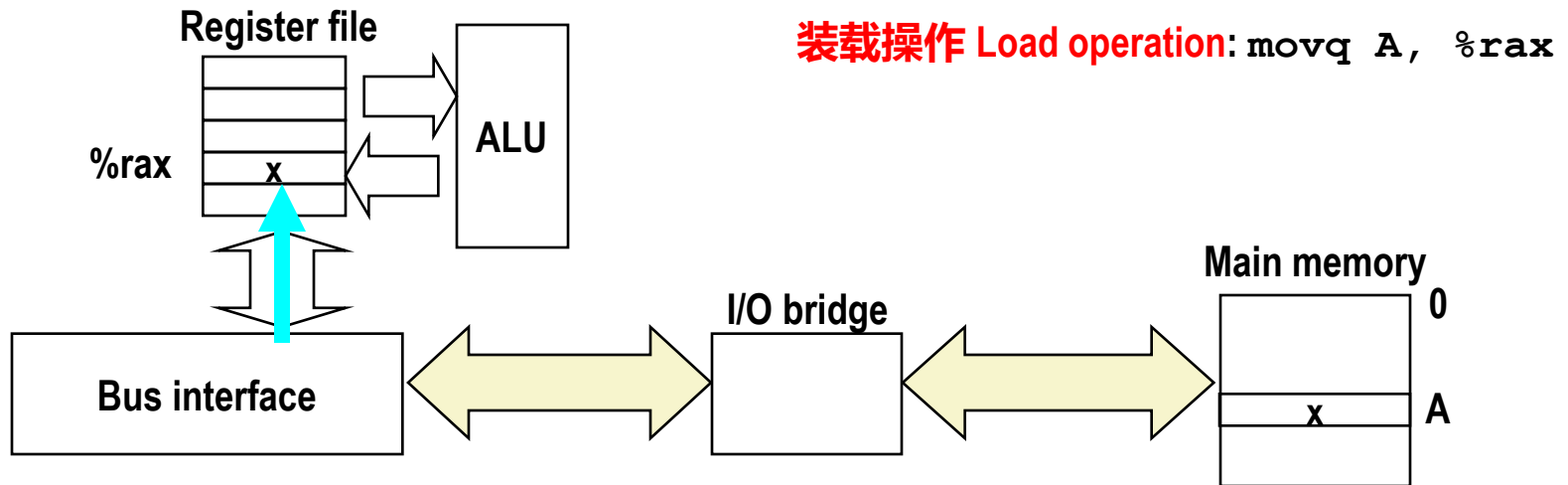




# 内存读事务 (3)

## Memory Read Transaction (3)

- CPU从总线读取x并拷贝到寄存器%rax中 CPU read word x from the bus and copies it into register %rax.

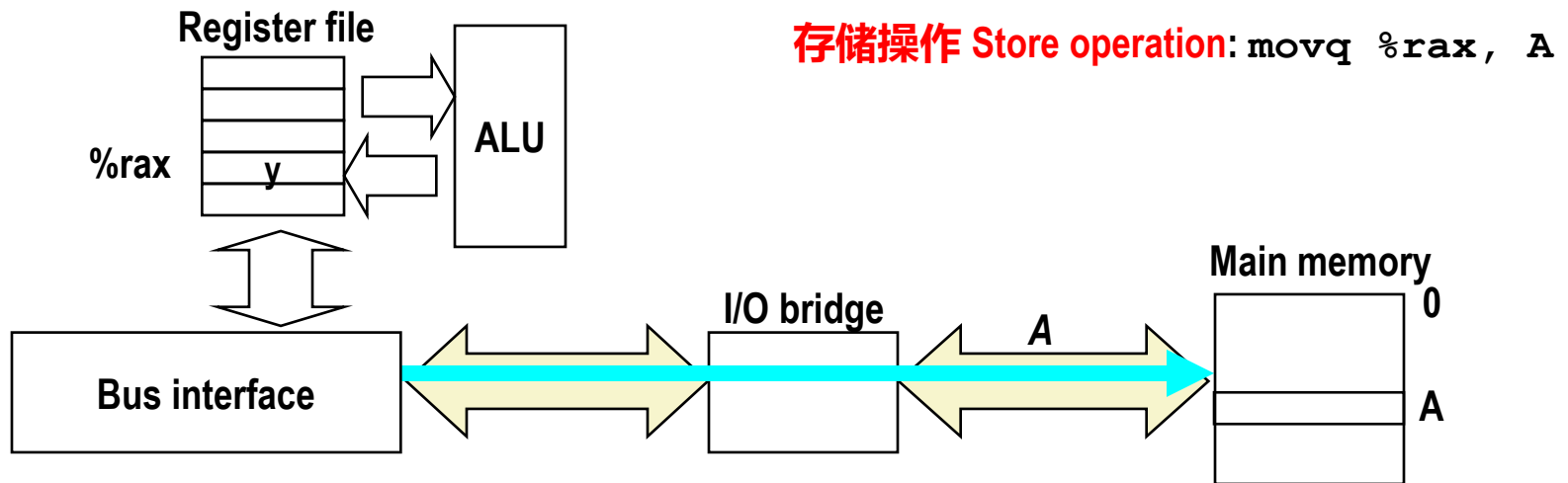




# 内存写事务 (1)

## Memory Write Transaction (1)

- CPU将地址A放到总线上，主存读取地址并等待数据字到来 CPU places address A on bus. Main memory reads it and waits for the corresponding data word to arrive.



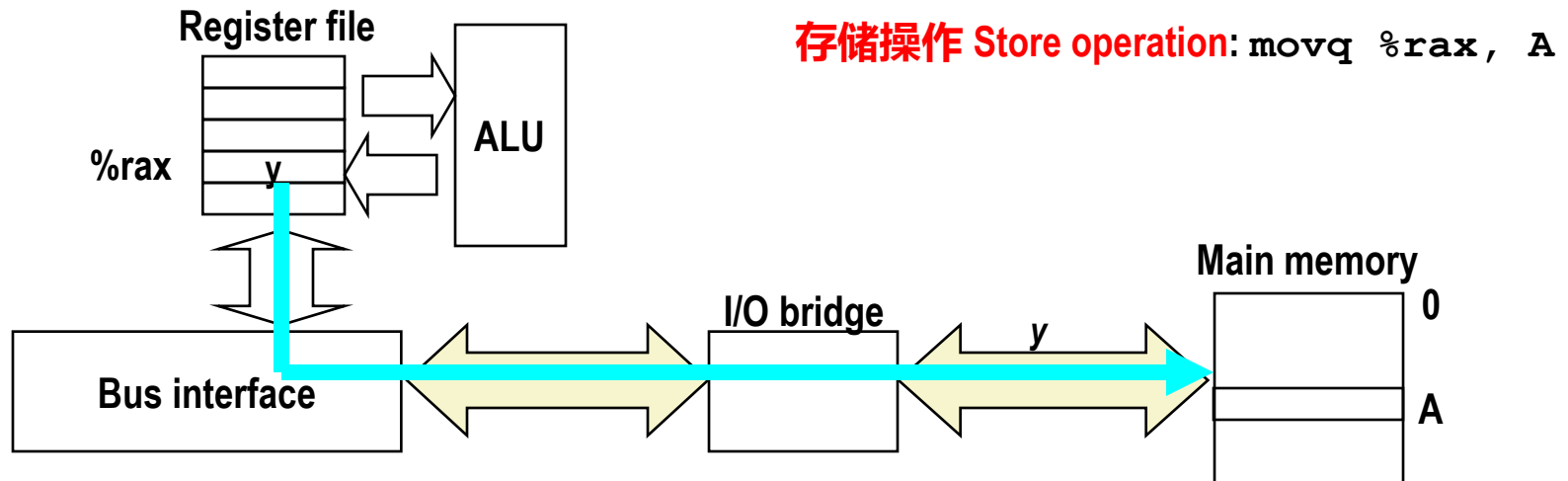




# 内存写事务 (2)

## Memory Write Transaction (2)

- CPU将数据字y放到总线上 CPU places data word y on the bus.

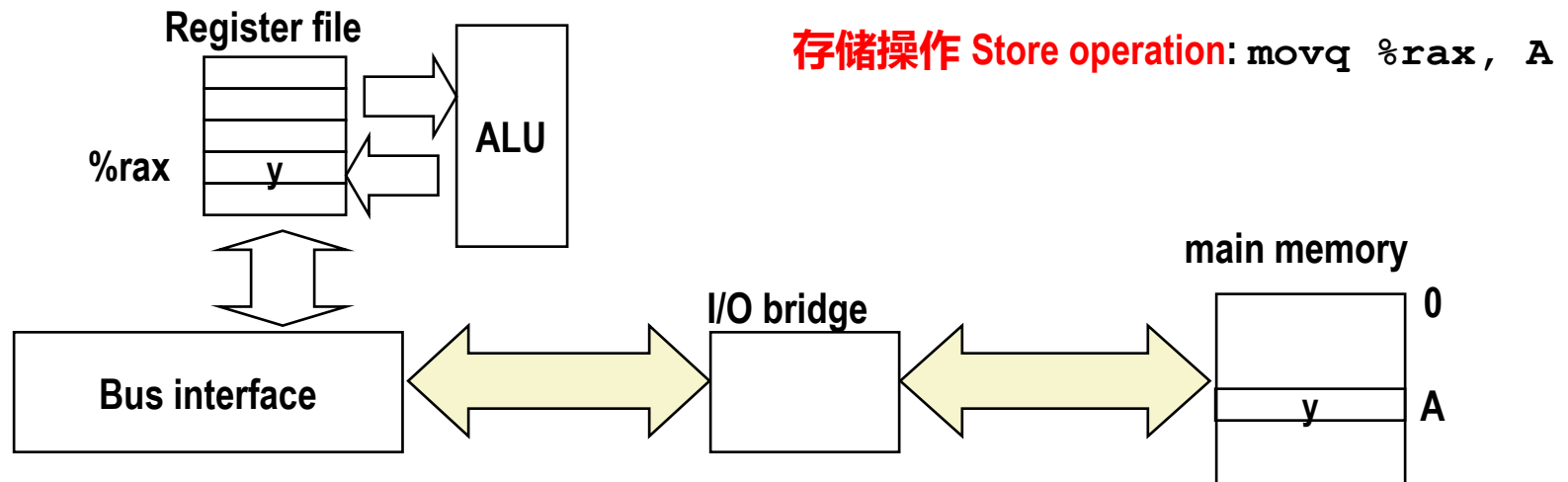




# 内存写事务 (3)

## Memory Write Transaction (3)

- 主存从总线读取数据字y并将其写入地址A Main memory reads data word y from the bus and stores it at address A.





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# 随机访问内存(RAM)

## Random-Access Memory (RAM)

### ■ 主要特点 Key features

- 传统上封装为一个芯片 **RAM** is traditionally packaged as a chip.
  - 或者嵌入到处理器芯片中 or embedded as part of processor chip
- 基本存储单元正常是一个cell (每个cell是一个bit) Basic storage unit is normally a **cell** (one bit per cell).
- 多个RAM芯片构成一个内存 Multiple RAM chips form a memory.

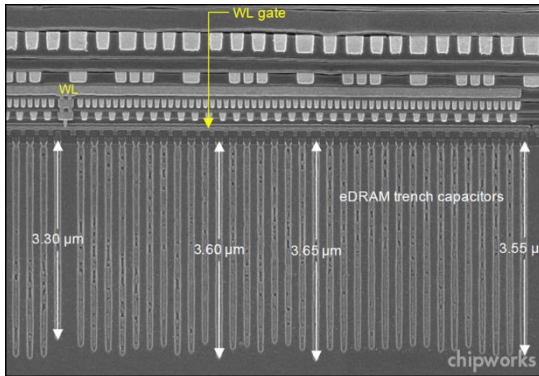
### ■ RAM有两种类型 RAM comes in two varieties:

- SRAM(静态RAM) SRAM (Static RAM)
- DRAM(动态RAM) DRAM (Dynamic RAM)

# RAM技术 RAM Technologies

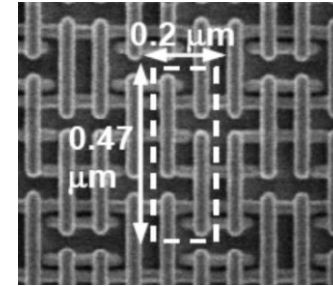


## ■ DRAM



- **每个比特需要一个晶体管+一个电容** 1 Transistor + 1 capacitor / bit
  - 电容器垂直定向 Capacitor oriented vertically
- **必须周期性刷新状态** Must refresh state periodically

## ■ SRAM



- **每个比特需要六个晶体管** 6 transistors / bit
- **永久保持状态** Holds state indefinitely

# SRAM vs DRAM Summary 小结



	Trans. per bit	Access time	Needs refresh?	Needs EDC?	Cost	Applications
SRAM	6 or 8	1x	No	Maybe	100x	Cache memories
DRAM	1	10x	Yes	Yes	1x	Main memories, frame buffers

EDC: 差错检测和纠正    EDC: Error detection and correction

## ■ 趋势 Trends

- SRAM随着半导体技术进展 SRAM scales with semiconductor technology
  - 达到其极限 Reaching its limits
- DRAM进展受最小电容需求限制 DRAM scaling limited by need for minimum capacitance
  - 纵横比限制了电容器的深度 Aspect ratio limits how deep can make capacitor
  - 也达到了其极限 Also reaching its limits

# 增强的DRAM

## Enhanced DRAMs



- **DRAM单元的操作从其发明开始没有变化** Operation of DRAM cell has not changed since its invention
  - 1970年由Intel商业化 Commercialized by Intel in 1970.
- **具有更好接口逻辑和更快I/O的DRAM核心** DRAM cores with better interface logic and faster I/O :
  - 同步DRAM (**SDRAM**) Synchronous DRAM (**SDRAM**)
    - 使用传统时钟信号代替异步控制 Uses a conventional clock signal instead of asynchronous control
  - 双倍数据率同步DRAM (**DDR SDRAM**) Double data-rate synchronous DRAM (**DDR SDRAM**)
    - 双边沿时钟每引脚每周期发送两位 Double edge clocking sends two bits per cycle per pin
    - 根据小型预取缓冲区的大小区分不同类型 Different types distinguished by size of small prefetch buffer:
      - **DDR** (2 bits), **DDR2** (4 bits), **DDR3** (8 bits), **DDR4** (16 bits)
    - 到2010年, 大多数服务器和桌面系统的标准配置 By 2010, standard for most server and desktop systems
    - Intel Core i7支持DDR3和DDR4 SDRAM Intel Core i7 supports DDR3 and DDR4 SDRAM

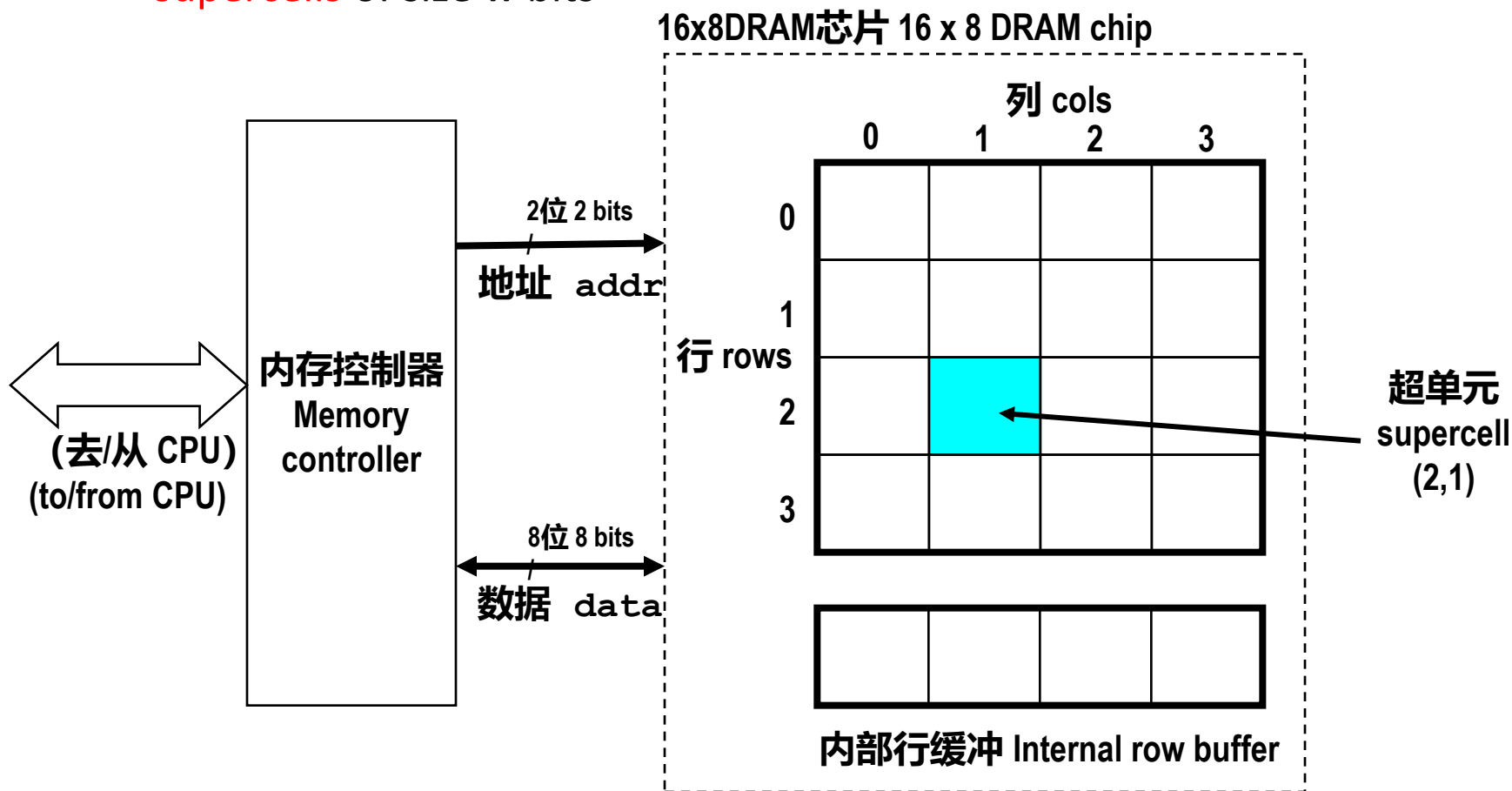
# 传统DRAM结构

## Conventional DRAM Organization



### ■ d x w DRAM:

- 总计 $d \cdot w$ 位组织成 $d$ 个 $w$ 位的**超单元**  $d \cdot w$  total bits organized as  $d$  **supercells** of size  $w$  bits





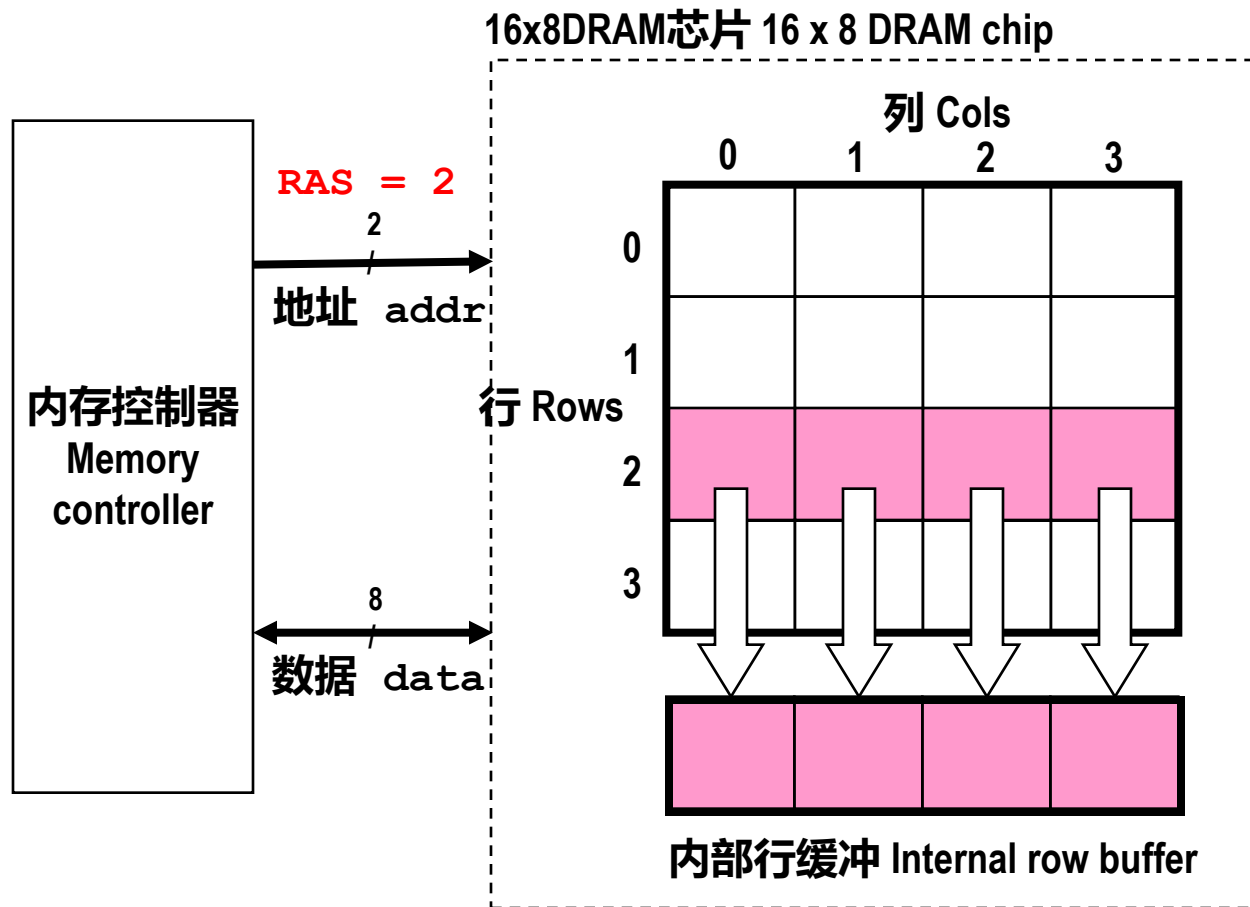


# 读取DRAM超单元

## Reading DRAM Supercell (2,1)

步骤1a: 行访问选通 (**RAS**) 选择第2行 Step 1(a): Row access strobe (**RAS**) selects row 2.

步骤1b: 第2行从DRAM矩阵复制到行缓冲 Step 1(b): Row 2 copied from DRAM array to row buffer.



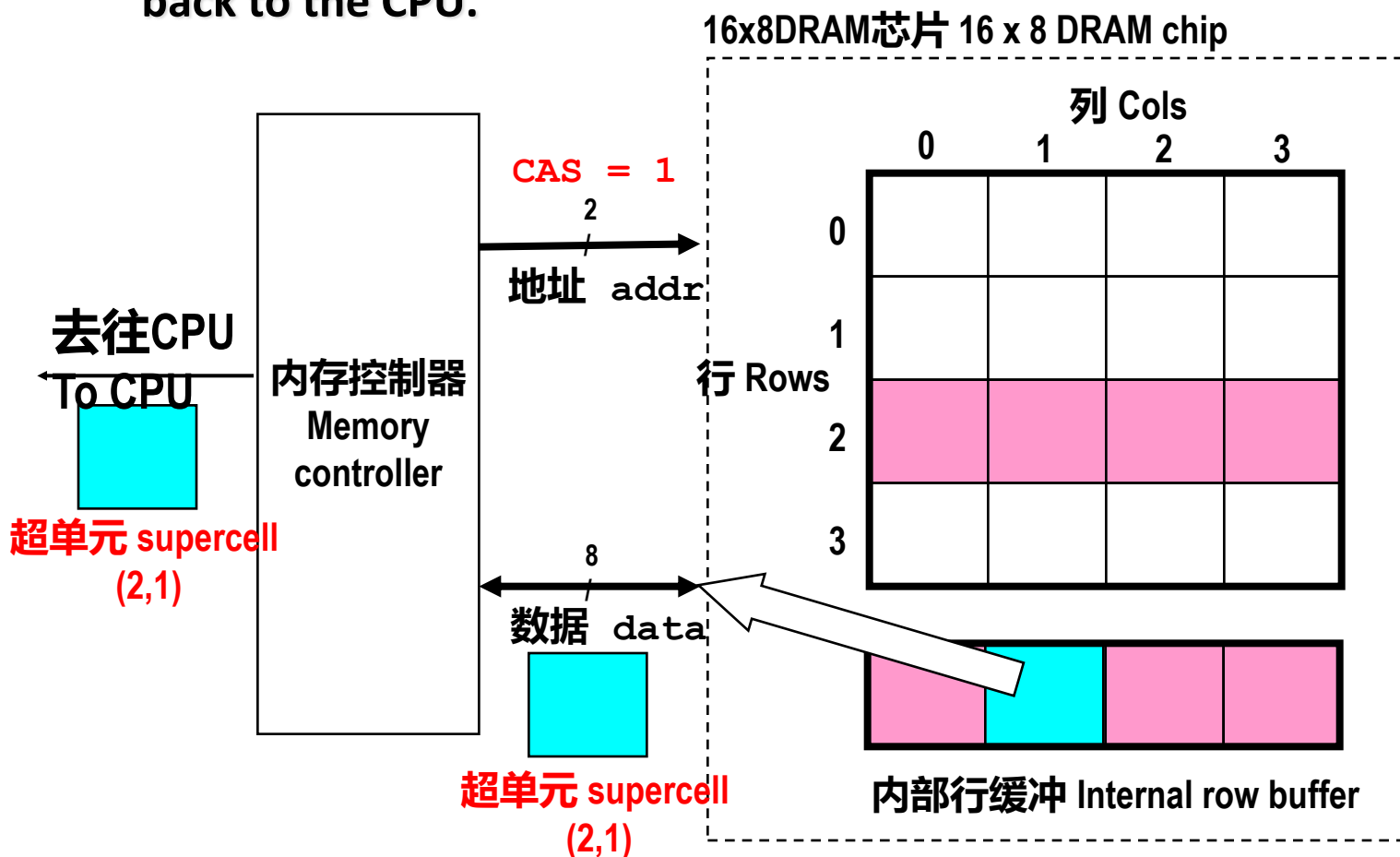


# 读取DRAM超单元

## Reading DRAM Supercell (2,1)

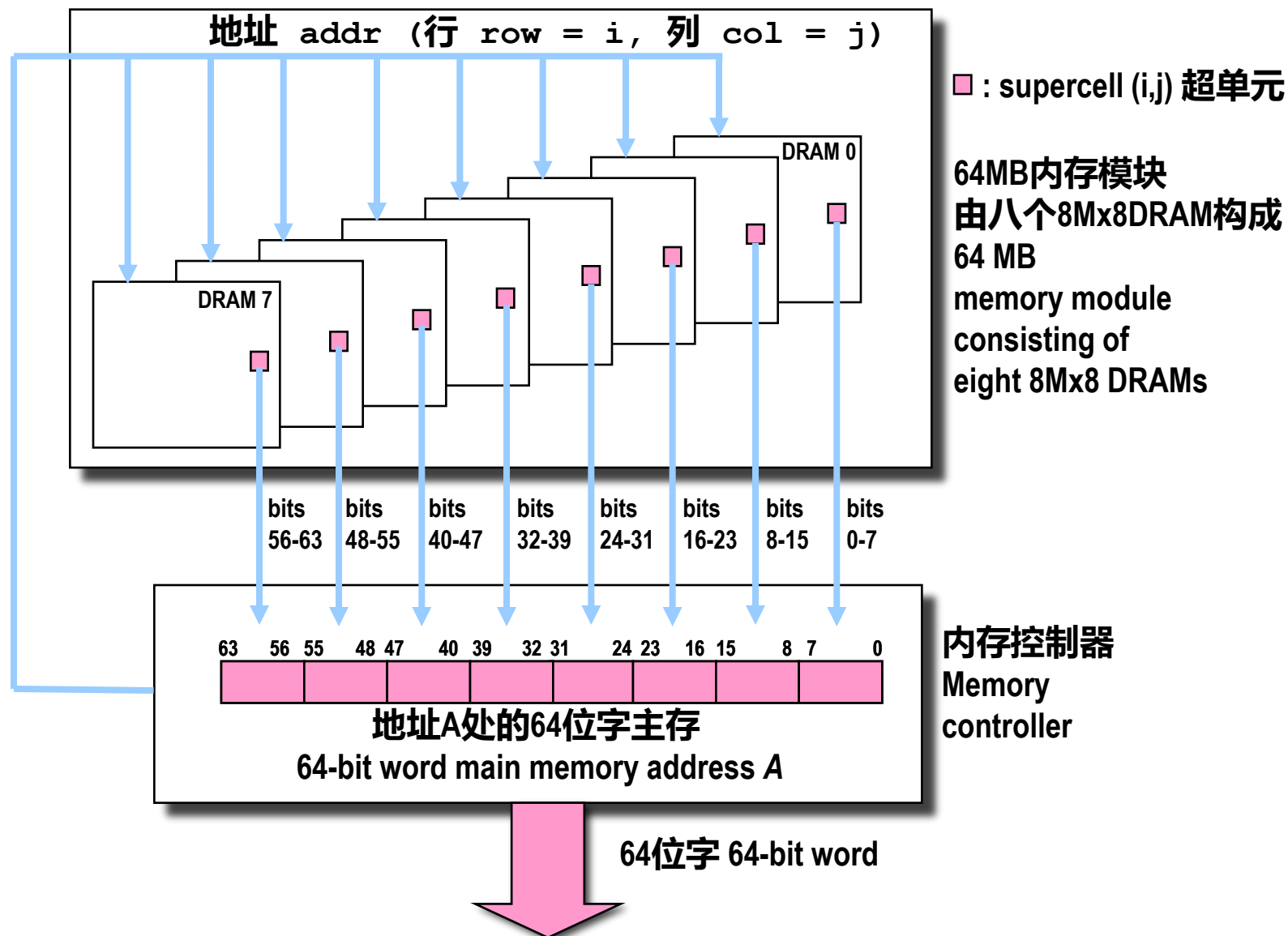
步骤2a: 列访问选通 (**CAS**) 选择第1列 Step 2(a): Column access strobe (**CAS**) selects column 1.

步骤2b: 超单元 (2, 1) 从缓冲区复制到数据线, 最终回到CPU Step 2(b): Supercell (2,1) copied from buffer to data lines, and eventually back to the CPU.



# 内存模块

## Memory Modules





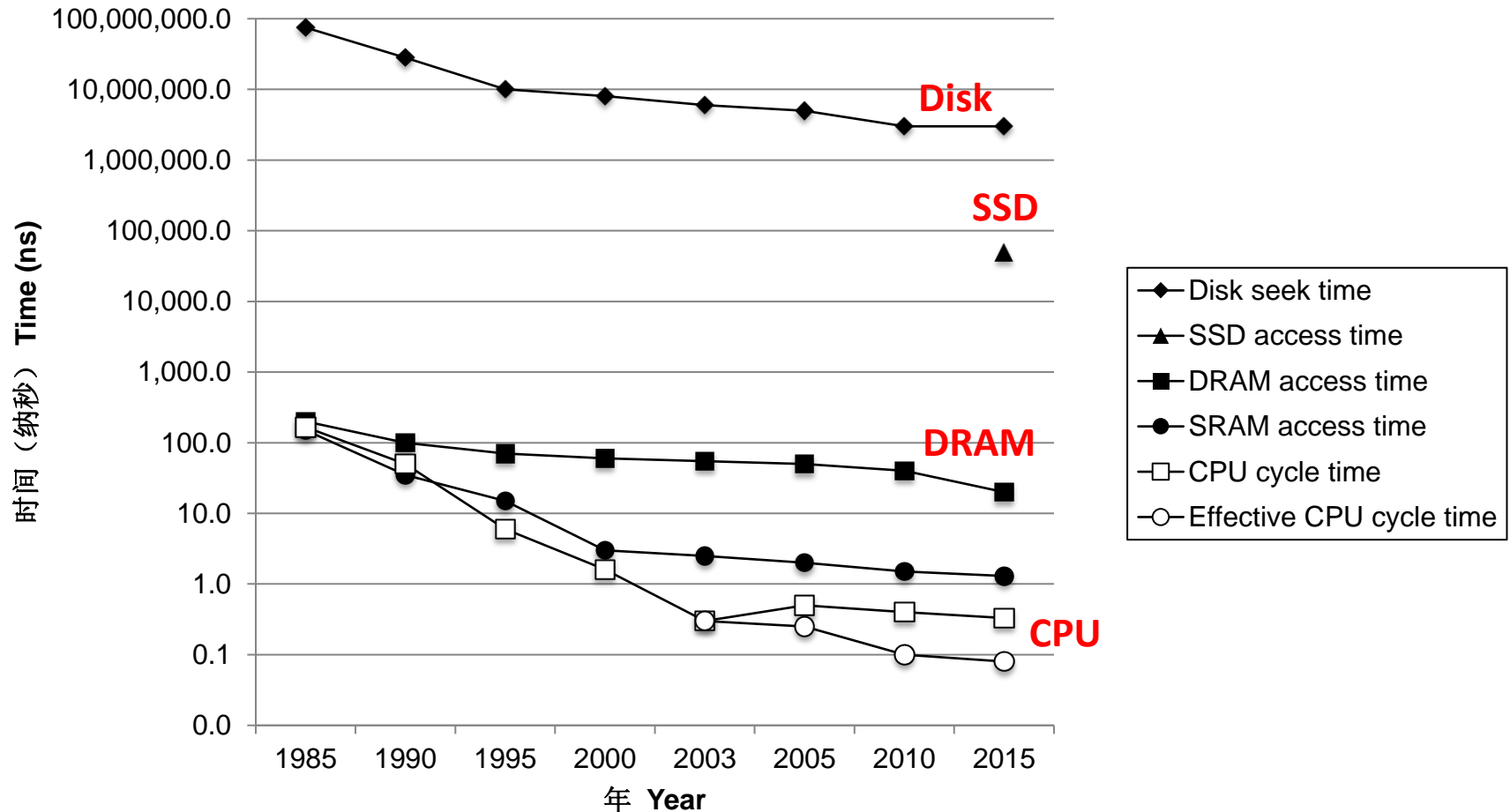
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# CPU-内存差距 The CPU-Memory Gap



**DRAM、磁盘和CPU之间速度的差距加大 The gap widens between DRAM, disk, and CPU speeds.**





# 局部性能够弥补这个差距

## Locality to the Rescue!

弥补CPU-内存之间速度差距的关键是计算机程序的一个基本属性，即局部性

The key to bridging this CPU-Memory gap is a fundamental property of computer programs known as **locality**

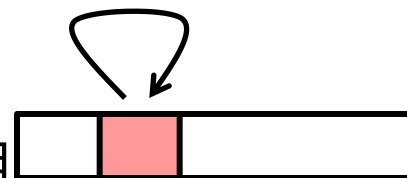
# 局部性 Locality



- **局部性原理：程序倾向于使用地址接近或等于其最近使用的地址的数据和指令** **Principle of Locality:** Programs tend to use data and instructions with addresses near or equal to those they have used recently

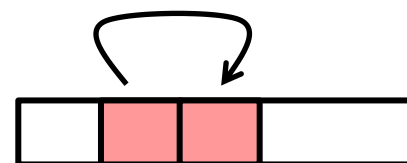
- **时间局部性 Temporal locality:**

- 最近引用的项目可能在不久的将来再次引用
- Recently referenced items are likely to be referenced again in the near future



- **空间局部性 Spatial locality:**

- 具有附近地址的项目往往在时间上被频繁地引用
- Items with nearby addresses tend to be referenced close together in time





# 局部性举例 Locality Example

```
sum = 0;  
for (i = 0; i < n; i++)  
    sum += a[i];  
return sum;
```

## ■ 数据访存 Data references

- 按序引用数组元素（步长-1的引用模式）  
Reference array elements in succession  
(stride-1 reference pattern).
- 每次迭代引用变量sum  
Reference variable `sum` each iteration.

**空间局部性**

**Spatial locality**

**时间局部性**

**Temporal locality**

## ■ 指令访存 Instruction references

- 顺序引用指令  
Reference instructions in sequence.
- 通过循环周期性重复  
Cycle through loop repeatedly.

**空间局部性**

**Spatial locality**

**时间局部性**

**Temporal locality**





# 局部性量化评估

## Qualitative Estimates of Locality

- **声明:** 对于专业程序员来说, 能够查看代码并对局部性进行量化评估是一项关键技能。 **Claim:** Being able to look at code and get a qualitative sense of its locality is a key skill for a professional programmer.
- **问题:** 这个函数对于数组a有良好的局部性吗?  
**Question:** Does this function have good locality with respect to array a?

**提示: 数组布局采用  
行优先顺序**

**Hint: array layout  
is row-major order**

**答案: 是 Answer: yes**

```
int sum_array_rows(int a[M][N])
{
    int i, j, sum = 0;

    for (i = 0; i < M; i++)
        for (j = 0; j < N; j++)
            sum += a[i][j];

    return sum;
}
```

a		a	a		a		a		a
[0]	...	[0]	[1]	...	[1]	...	[M-1]	...	[M-1]
[0]		[N-1]	[0]		[N-1]		[0]		[N-1]

# 局部性示例 Locality Example



- **问题：**这个函数对于数组a有良好的局部性吗？

**Question:** Does this function have good locality with respect to array a?

```
int sum_array_cols(int a[M][N])
{
    int i, j, sum = 0;

    for (j = 0; j < N; j++)
        for (i = 0; i < M; i++)
            sum += a[i][j];
    return sum;
}
```

**答案：否，除非。。。。**

**Answer: no, unless...**

**M非常小 M is very small**

a		a	a		a		a		a
[0]	...	[0]	[1]	...	[1]	...	[M-1]	...	[M-1]
[0]		[N-1]	[0]		[N-1]		[0]		[N-1]



# 局部性示例 Locality Example

- **问题：**您能否排列循环，以便该函数使用步长-1引用模式扫描三维数组a（从而具有良好的空间局部性）？

**Question:** Can you permute the loops so that the function scans the 3-d array a with a stride-1 reference pattern (and thus has good spatial locality)?

```
int sum_array_3d(int a[M][N][N])
{
    int i, j, k, sum = 0;

    for (i = 0; i < N; i++)
        for (j = 0; j < N; j++)
            for (k = 0; k < M; k++)
                sum += a[k][i][j];

    return sum;
}
```

**答案：让j成为最内循环** Answer: make j the inner loop



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# 存储层次结构 Memory Hierarchies



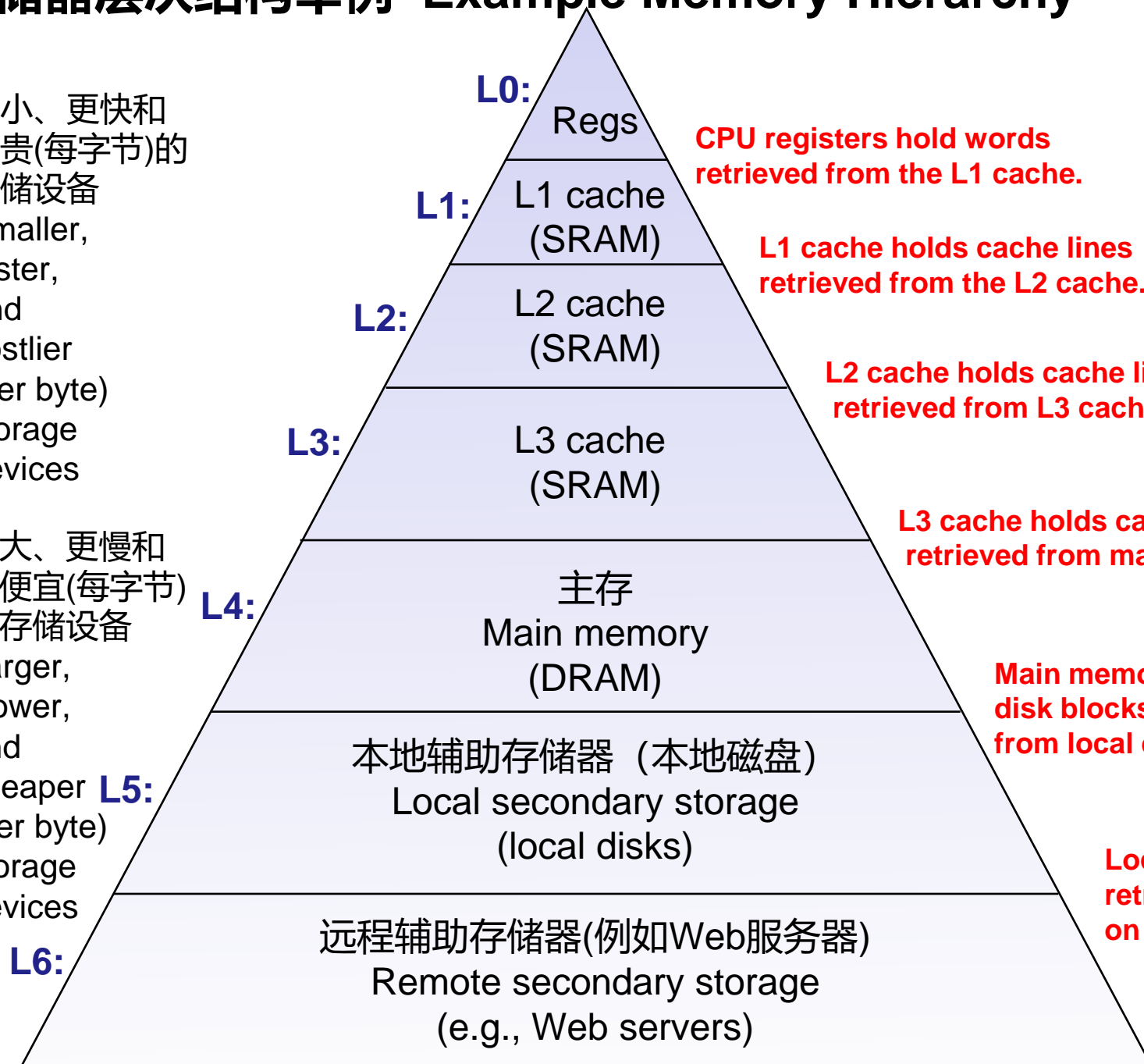
- **硬件和软件的一些基本和持久特性： Some fundamental and enduring properties of hardware and software:**
  - 快速存储技术每字节成本更高，容量更小，并且需要更大功率（发热！） Fast storage technologies cost more per byte, have less capacity, and require more power (heat!).
  - CPU和主存之间的速度差距正在扩大 The gap between CPU and main memory speed is widening.
  - 写得好的程序往往具有良好的局部性 Well-written programs tend to exhibit good locality.
- **对于许多类型的程序，这些属性可以很好地相互补充。**  
These properties complement each other well for many types of programs.
- **他们提出了一种组织内存和存储系统的方法，称为存储器层次结构** They suggest an approach for organizing memory and storage systems known as a **memory hierarchy**.



# 存储器层次结构举例 Example Memory Hierarchy

↑  
更小、更快和  
更贵(每字节)的  
存储设备  
Smaller,  
faster,  
and  
costlier  
(per byte)  
storage  
devices

↓  
更大、更慢和  
更便宜(每字节)  
的存储设备  
Larger,  
slower,  
and  
cheaper  
(per byte)  
storage  
devices



CPU registers hold words  
retrieved from the L1 cache.

L1 cache holds cache lines  
retrieved from the L2 cache.

L2 cache holds cache lines  
retrieved from L3 cache

L3 cache holds cache lines  
retrieved from main memory.

Main memory holds  
disk blocks retrieved  
from local disks.

Local disks hold files  
retrieved from disks  
on remote servers

# 高速缓存 Caches



- **缓存:** 一种较小、较快的存储设备, 用作较大、较慢设备中数据子集的暂存区域。 **Cache:** A smaller, faster storage device that acts as a staging area for a subset of the data in a larger, slower device.
- **存储器层次结构的基本思想:** Fundamental idea of a memory hierarchy:
  - 对于每个 $k$ , 级别为 $k$ 的更快、更小的设备充当级别为 $k+1$ 的更大、更慢设备的缓存 For each  $k$ , the faster, smaller device at level  $k$  serves as a cache for the larger, slower device at level  $k+1$ .
- **为什么存储器层次结构有效?** Why do memory hierarchies work?
  - 由于局部性的原因: 程序倾向于访问 $k$ 级的数据, 而不是访问 $k+1$ 级的数据 Because of locality, programs tend to access the data at level  $k$  more often than they access the data at level  $k+1$ .
  - 因此,  $k+1$ 级的存储速度可能较慢, 因此存储量更大、每比特的成本更低。 Thus, the storage at level  $k+1$  can be slower, and thus larger and cheaper per bit.

# 高速缓存 Caches

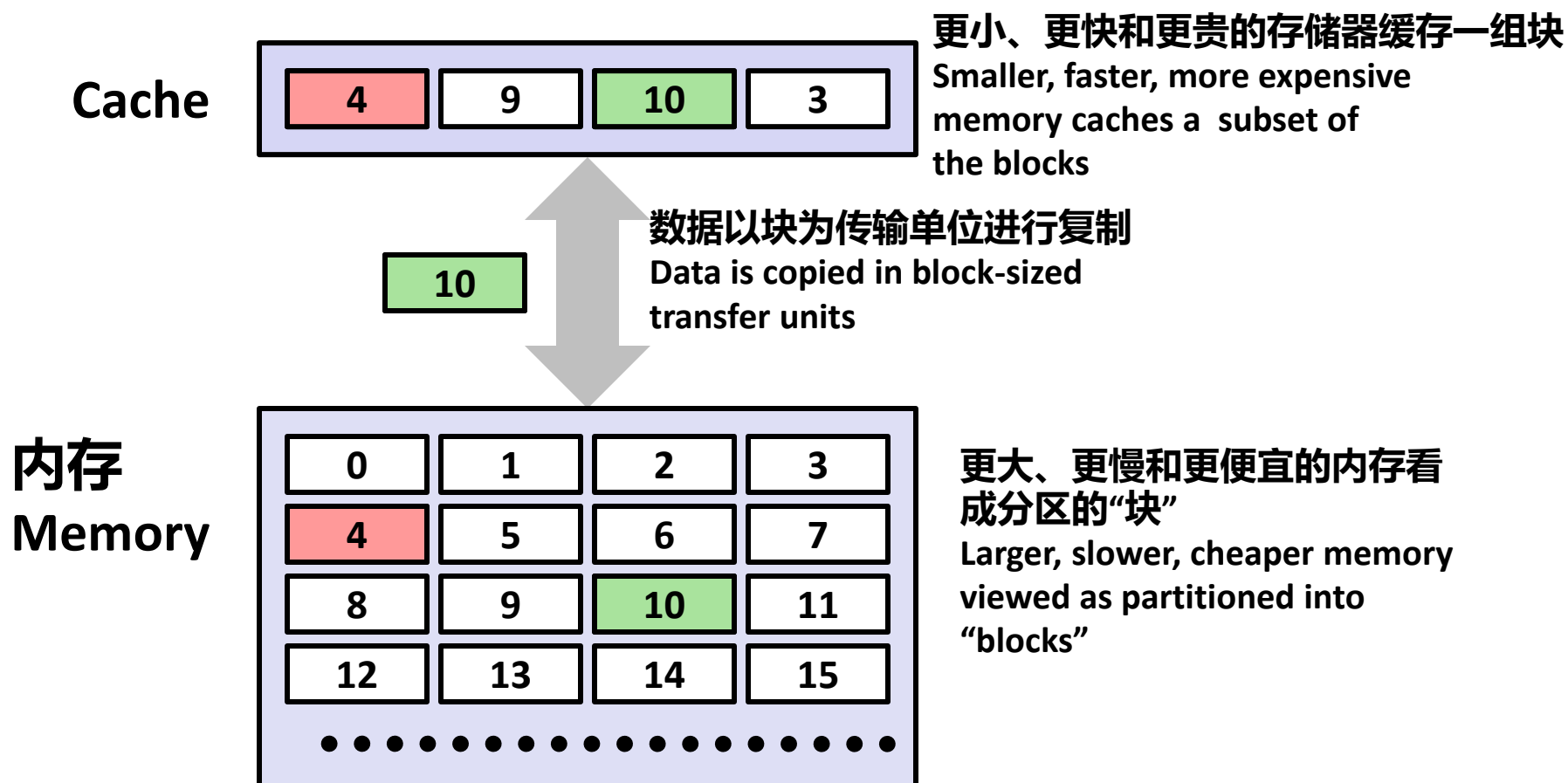


- **大思想：**存储器层次结构创建了一个大的存储池，其成本与底部的廉价存储一样多，但它以接近顶部的快速存储速率向程序提供数据。
- **Big Idea:** The memory hierarchy creates a large pool of storage that costs as much as the cheap storage near the bottom, but that serves data to programs at the rate of the fast storage near the top.



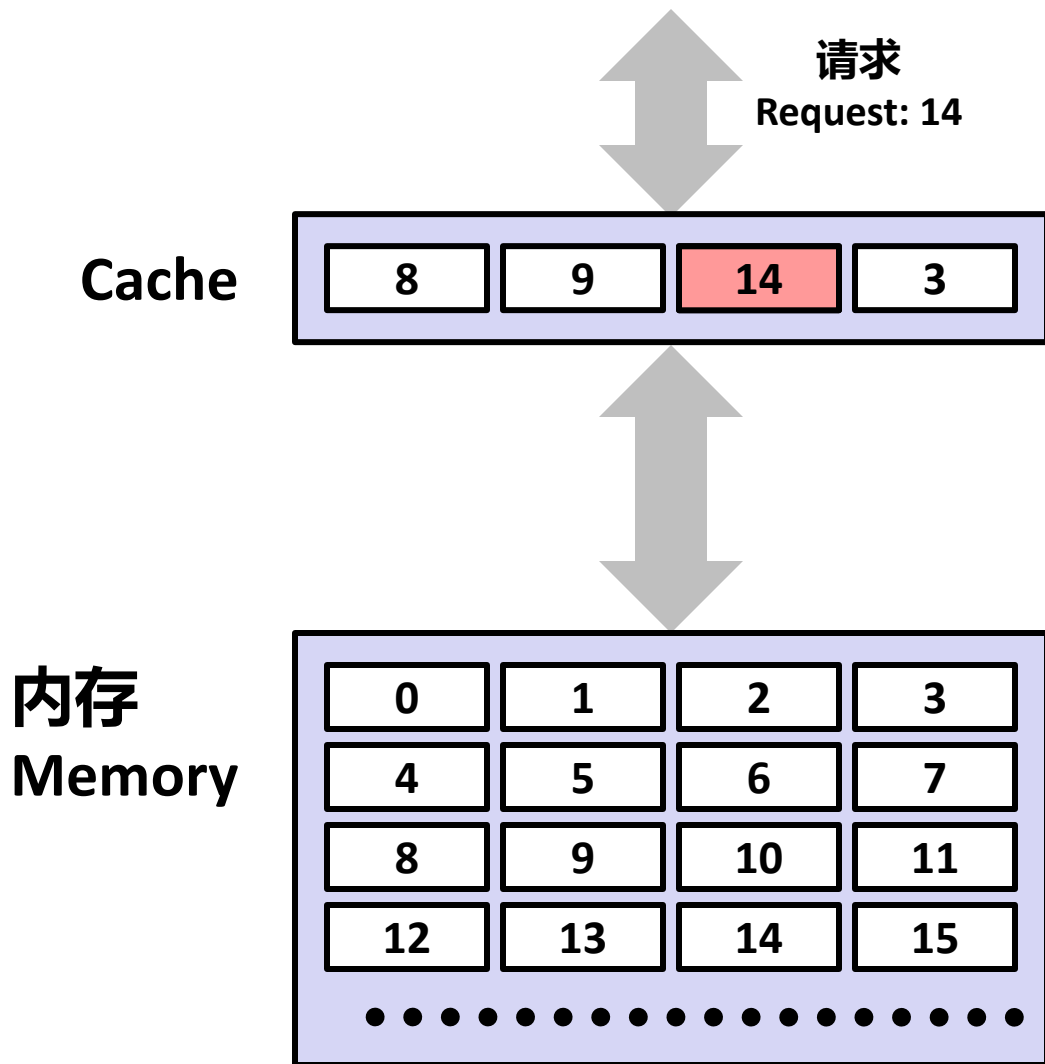


# Cache一般概念 General Cache Concepts



# Cache一般概念：命中

## General Cache Concepts: Hit



*需要数据块 b*

*Data in block b is needed*

*块 b 在 cache 中:*

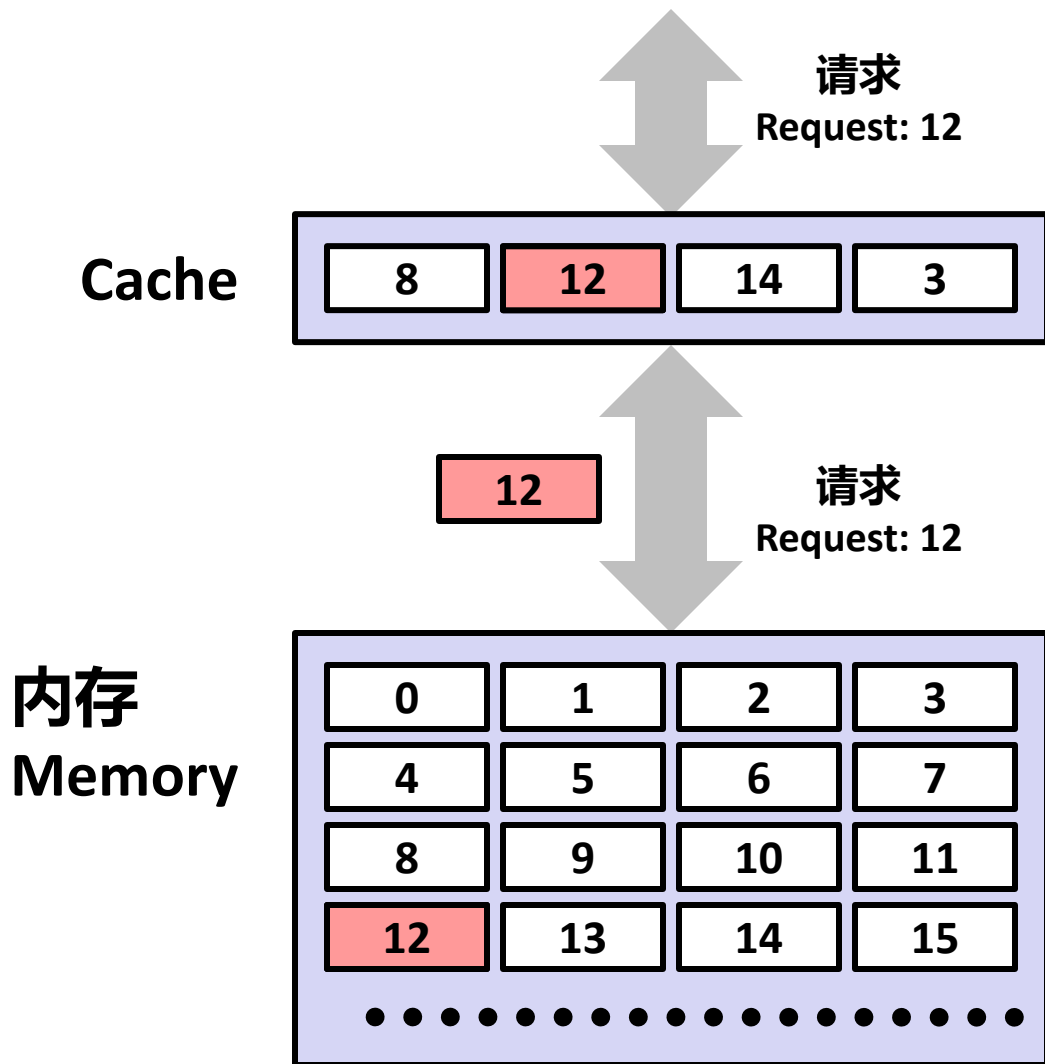
***命中!***

*Block b is in cache:*

***Hit!***

# Cache一般概念：不命中

## General Cache Concepts: Miss



**需要数据块  $b$**

*Data in block  $b$  is needed*

**块  $b$  没在 cache 中:**

**不命中!**

*Block  $b$  is not in cache:*

**Miss!**

**从内存取块  $b$**

*Block  $b$  is fetched from memory*

**Cache 中存储的块  $b$**

*Block  $b$  is stored in cache*

- **放置策略:** 确定  $b$  放在哪

**Placement policy:**

determines where  $b$  goes

- **替换策略:** 确定驱逐哪个块 (牺牲)

**Replacement policy:**

determines which block gets evicted (victim)

# Cache一般概念：Cache不命中类型

## General Caching Concepts: Types of Cache Misses



### ■ 冷 (强制) 不命中 Cold (compulsory) miss

- 因为cache为空而发生冷不命中 Cold misses occur because the cache is empty.

### ■ 冲突不命中 Conflict miss

- 大多数缓存将k+1级的块限制为k级块位置的一个小子集 (有时是单个位置)  
Most caches limit blocks at level k+1 to a small subset (sometimes a singleton) of the block positions at level k.
  - 例如k+1层的块i必须放置在k层的块  $(i \bmod 4)$  中 E.g. Block i at level k+1 must be placed in block  $(i \bmod 4)$  at level k.
- 当k级缓存足够大, 但多个数据对象都映射到同一个k级块时, 就会发生冲突不命中 Conflict misses occur when the level k cache is large enough, but multiple data objects all map to the same level k block.
  - 例如引用块0、8、0、8, 0、8...每次都会不命中 E.g. Referencing blocks 0, 8, 0, 8, 0, 8, ... would miss every time.

### ■ 容量不命中 Capacity miss

- 当活动缓存块集 (工作集) 大于缓存时发生 Occurs when the set of active cache blocks (**working set**) is larger than the cache.



## 存储器层次结构中的Cache举例

### Examples of Caching in the Mem. Hierarchy

Cache类型 Cache Type	缓存什么? What is Cached?	缓存到哪儿? Where is it Cached?	延迟 (周期) Latency (cycles)	管理 Managed By
Registers	4-8 bytes words	CPU core	0	Compiler
TLB	Address translations	On-Chip TLB	0	Hardware MMU
L1 cache	64-byte blocks	On-Chip L1	4	Hardware
L2 cache	64-byte blocks	On-Chip L2	10	Hardware
Virtual Memory	4-KB pages	Main memory	100	Hardware + OS
Buffer cache	Parts of files	Main memory	100	OS
Disk cache	Disk sectors	Disk controller	100,000	Disk firmware
Network buffer cache	Parts of files	Local disk	10,000,000	NFS client
Browser cache	Web pages	Local disk	10,000,000	Web browser
Web cache	Web pages	Remote server disks	1,000,000,000	Web proxy server



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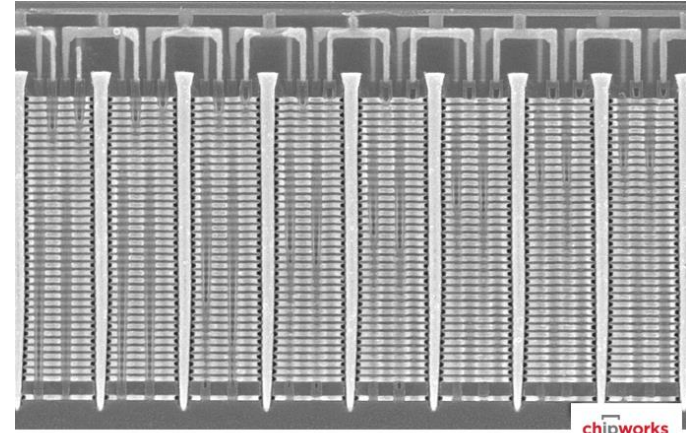


## ■ 磁盘 Magnetic Disks



- 存储在磁介质上 Store on magnetic medium
- 电子机械访问 Electromechanical access

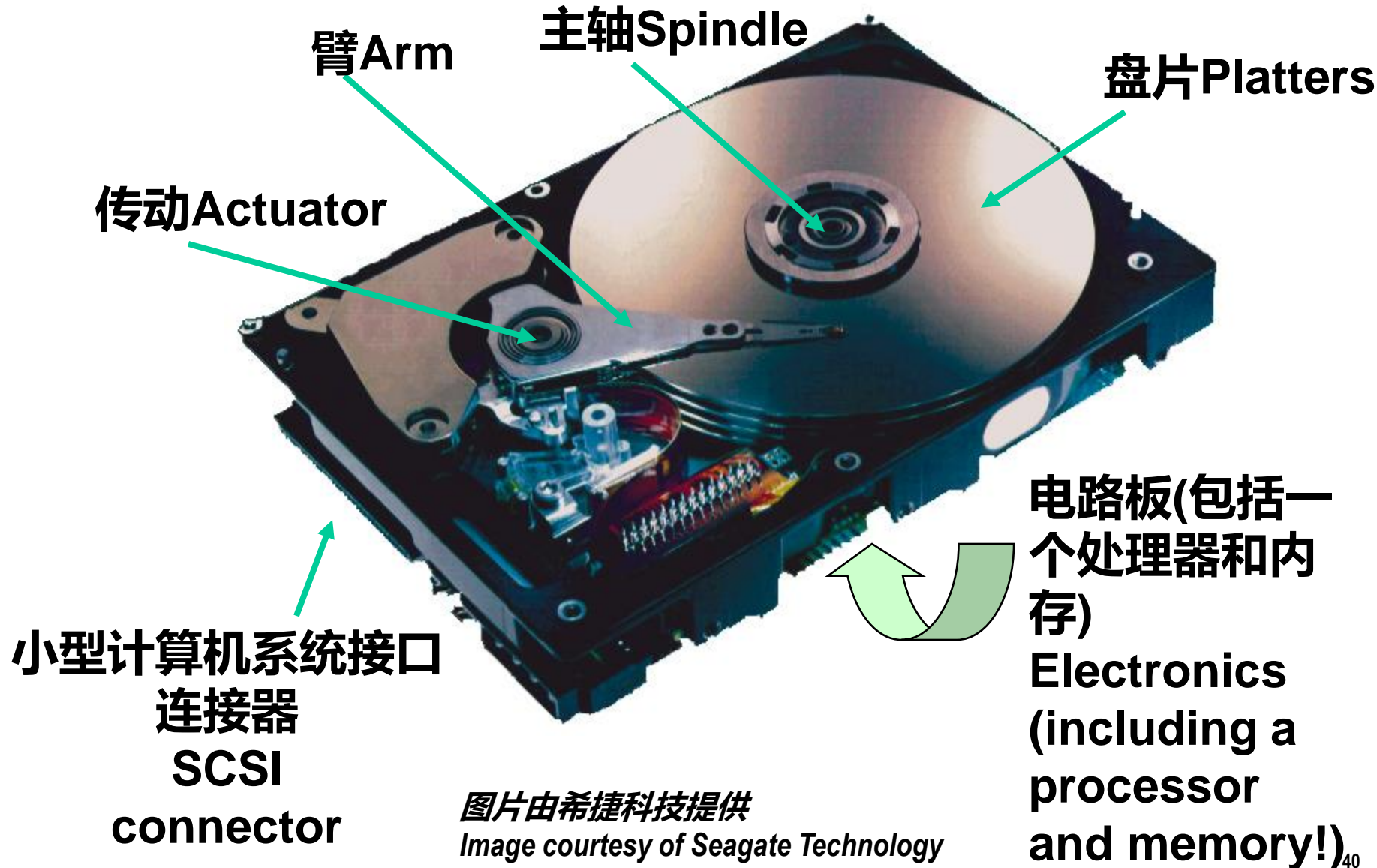
## ■ 非易失（闪存）存储器 Nonvolatile (Flash) Memory



Close-up image of V-NAND flash array

- 永久性存储 Store as persistent charge
- 用三维结构实现 Implemented with 3-D structure
  - 100以上的单元级别 100+ levels of cells
  - 每个单元3-4位数据 3-4 bits data per cell

# 硬盘驱动器内部有什么？ What's Inside A Disk Drive?

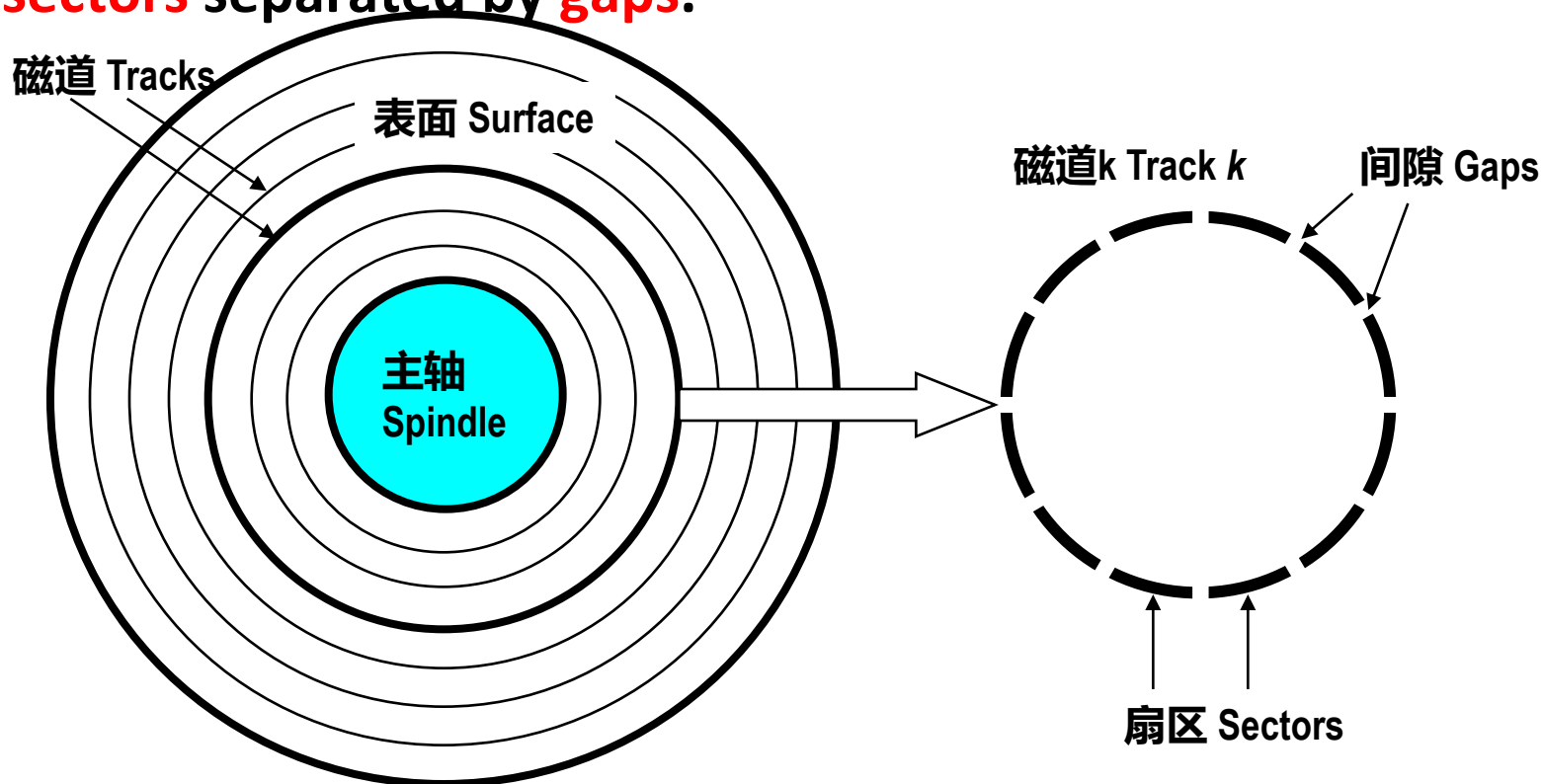




# 磁盘结构 Disk Geometry



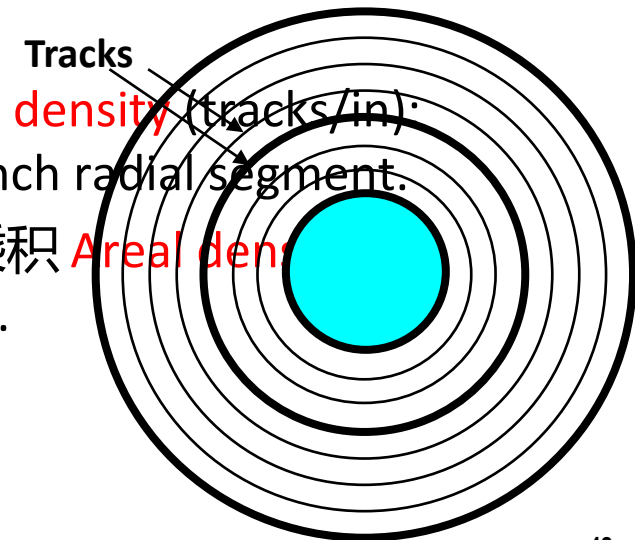
- 磁盘由**盘片**构成，每个有两个**表面** Disks consist of **platters**, each with two **surfaces**.
- 每个表面由同心圆环构成，称为**磁道** Each surface consists of concentric rings called **tracks**.
- 每个磁道由**扇区**构成，中间用**间隙**分隔 Each track consists of **sectors** separated by **gaps**.



# 磁盘容量 Disk Capacity



- **容量：可以存储的最大位数** **Capacity**: maximum number of bits that can be stored.
  - 供应商表示容量以GB为单位，其中1 GB =  $10^9$  字节 Vendors express capacity in units of gigabytes (GB), where 1 GB =  $10^9$  Bytes.
- **容量由这些技术因素确定** **Capacity is determined by these technology factors:**
  - **记录密度**(位/英寸)：一个磁道中1英寸段存储的位数 **Recording density** (bits/in): number of bits that can be squeezed into a 1 inch segment of a track.
  - **道密度**(道/英寸)：1英寸半径段的磁道数 **Track density** (tracks/in): number of tracks that can be squeezed into a 1 inch radial segment.
  - **面密度**(位/平方英寸)：记录密度和道密度的乘积 **Areal density** (bits/in<sup>2</sup>): product of recording and track density.

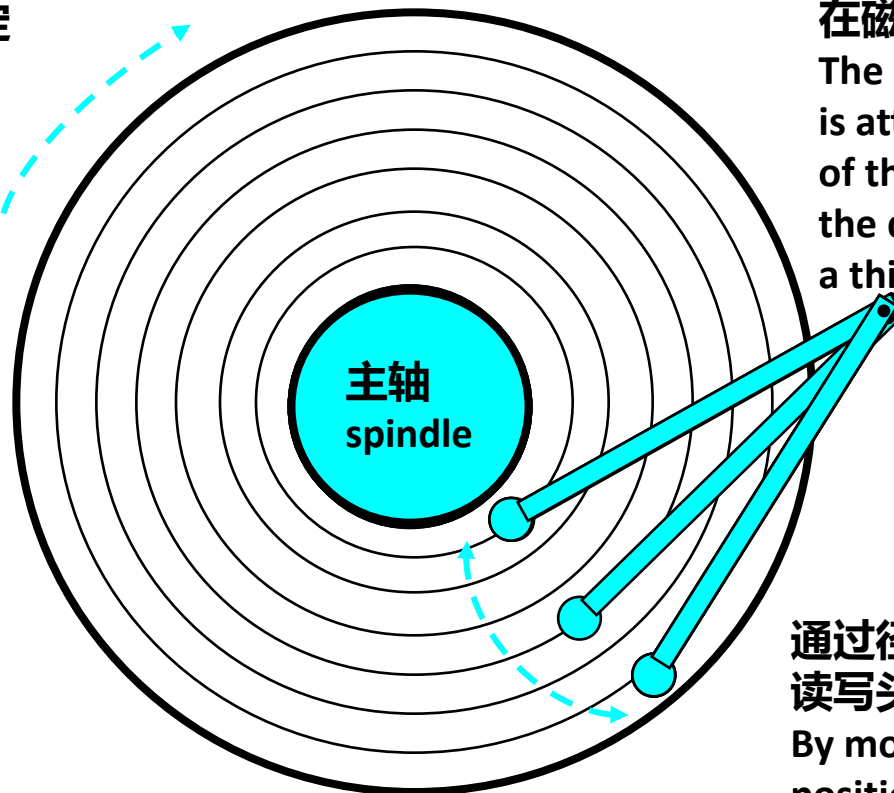


# 磁盘操作 (单盘片视图)

## Disk Operation (Single-Platter View)



磁盘表面以固定  
旋转速率旋转  
The disk surface  
spins at a fixed  
rotational rate



读/写头连接到传动臂末端，悬浮  
在磁盘表面上飞过

The read/write *head*  
is attached to the end  
of the *arm* and flies over  
the disk surface on  
a thin cushion of air.

通过径向移动，传动臂可以将  
读写头放在任何磁道上。

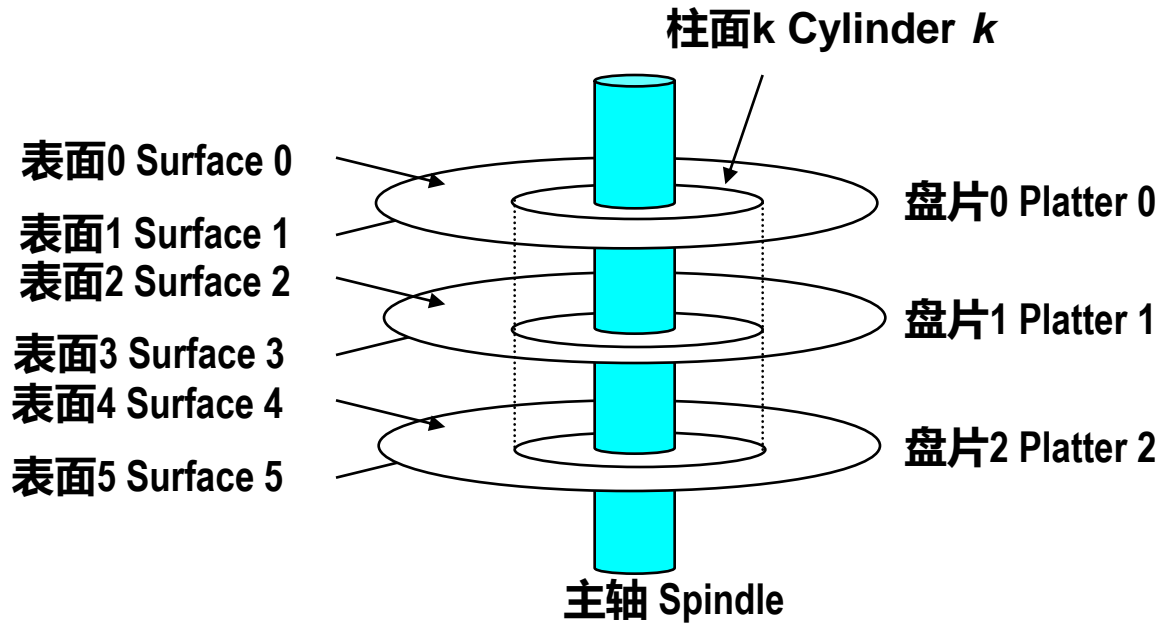
By moving radially, the arm can  
position the read/write head  
over any track.



# 磁盘操作（多盘片视图）

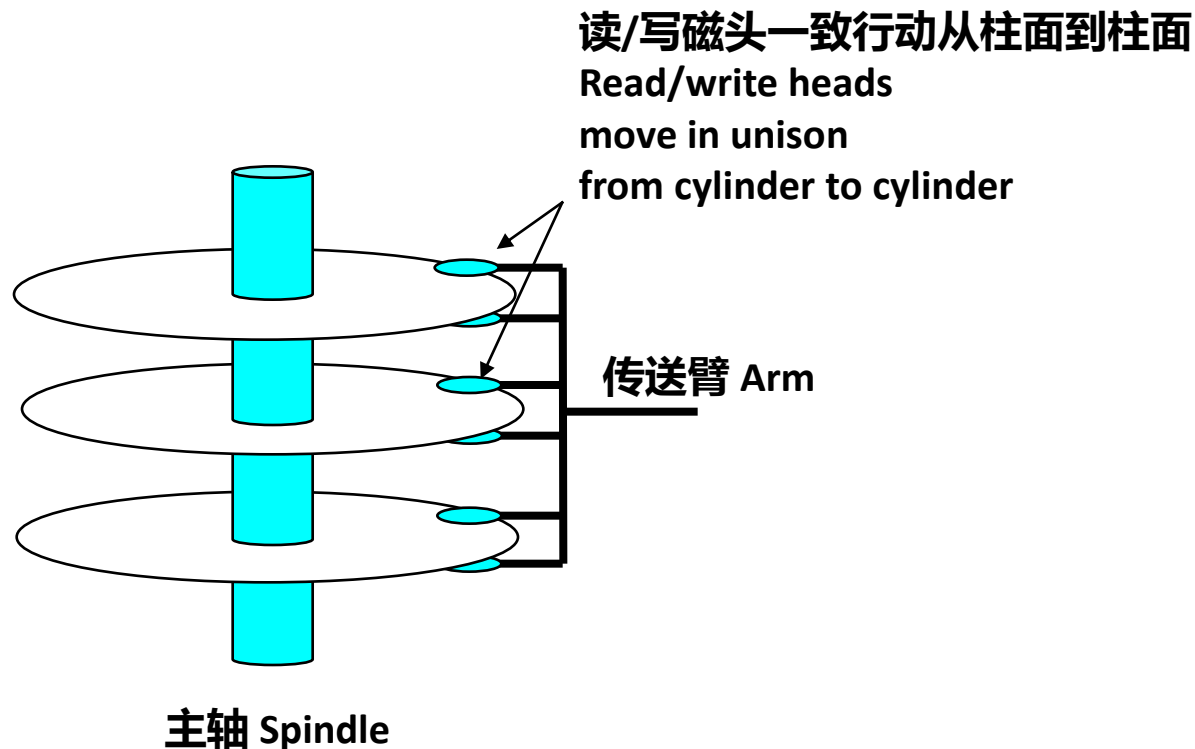
## Disk Operation (Multiple-Platter View)

- 同心磁道形成一个柱面 Aligned tracks form a cylinder.



# 磁盘操作 (多盘片视图)

## Disk Operation (Multi-Platter View)

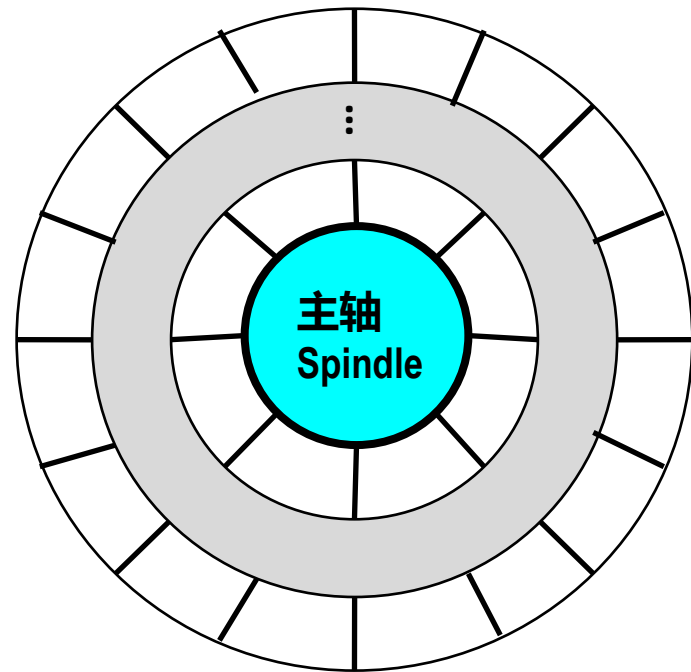


# 记录区 Recording zones



- 现代磁盘把磁道分区成不相交的子集，称为**记录区** Modern disks partition tracks into disjoint subsets called **recording zones**

- 在区内每个磁道有同样的扇区数，由最内磁道的圆周确定 Each track in a zone has the same number of sectors, determined by the circumference of innermost track.
- 每个区有不同每道扇区数，外侧区比内侧区有更多的每道扇区数 Each zone has a different number of sectors/track, outer zones have more sectors/track than inner zones.
- 因此当计算容量时我们使用**平均**每道扇区数 So we use **average** number of sectors/track when computing capacity.





# 计算磁盘容量 Computing Disk Capacity

容量 = 字节数/扇区 x 平均扇区数/磁道 x  
磁道数/面 x 表面数/盘片 x 盘片数/磁盘

Capacity = (# bytes/sector) x (avg. # sectors/track) x  
(# tracks/surface) x (# surfaces/platter) x  
(# platters/disk)

例如: Example:

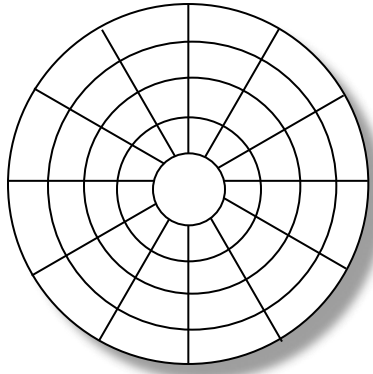
- 512 bytes/sector 字节数/扇区
- 300 sectors/track (on average) 扇区数/磁道 (平均)
- 20,000 tracks/surface 磁道数/面
- 2 surfaces/platter 表面数/盘片
- 5 platters/disk 盘片数/磁盘

容量 Capacity = 512 x 300 x 20000 x 2 x 5  
= 30,720,000,000  
= 30.72 GB



# 磁盘结构-单个盘片的顶层视图

Disk Structure - top view of single platter



**表面组织成磁道**

**Surface organized into tracks**

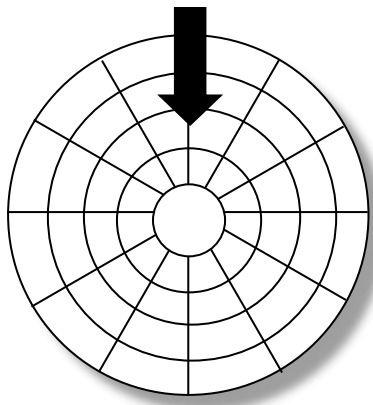
**磁道分成扇区**

**Tracks divided into sectors**





# 磁盘访问 Disk Access

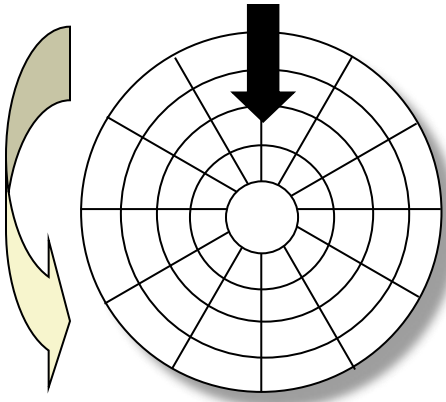


**磁头在磁道上某个位置**

**Head in position above a track**



# 磁盘访问 Disk Access

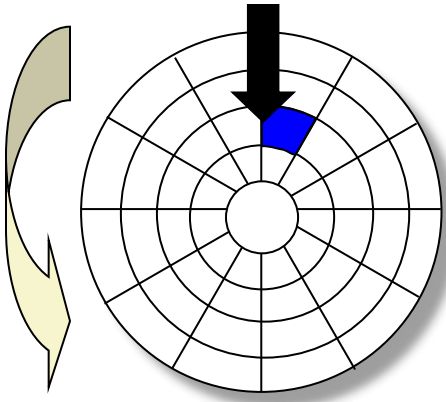


**逆时针旋转**

**Rotation is counter-clockwise**



# 磁盘访问-读 Disk Access – Read

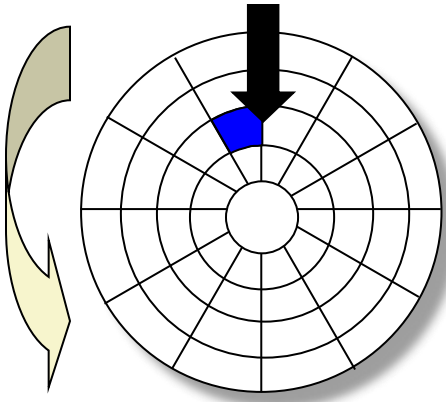


**准备读取蓝色扇区**

**About to read blue sector**



# 磁盘访问-读 Disk Access – Read



读蓝色扇区后

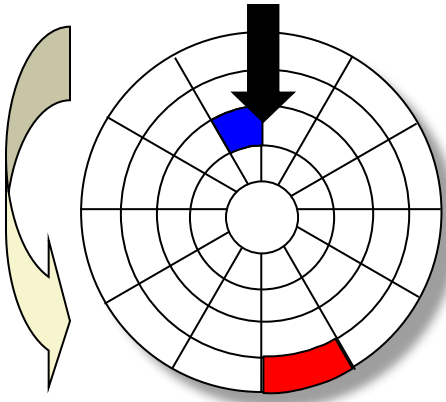
After BLUE read

读取蓝色扇区之后

After reading blue sector



# 磁盘访问-读 Disk Access – Read



读蓝色扇区后

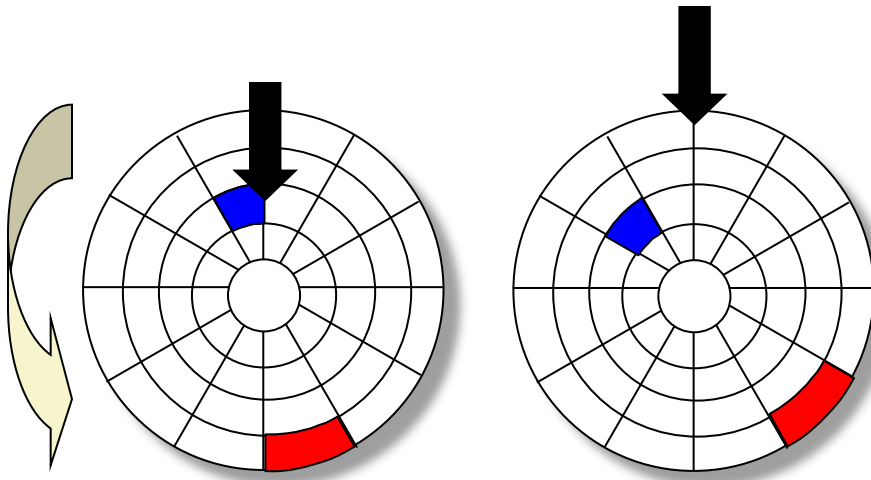
After BLUE read

下次请求调度红色扇区

Red request scheduled next



# 磁盘访问-寻道 Disk Access – Seek



读蓝色扇区后

After BLUE read

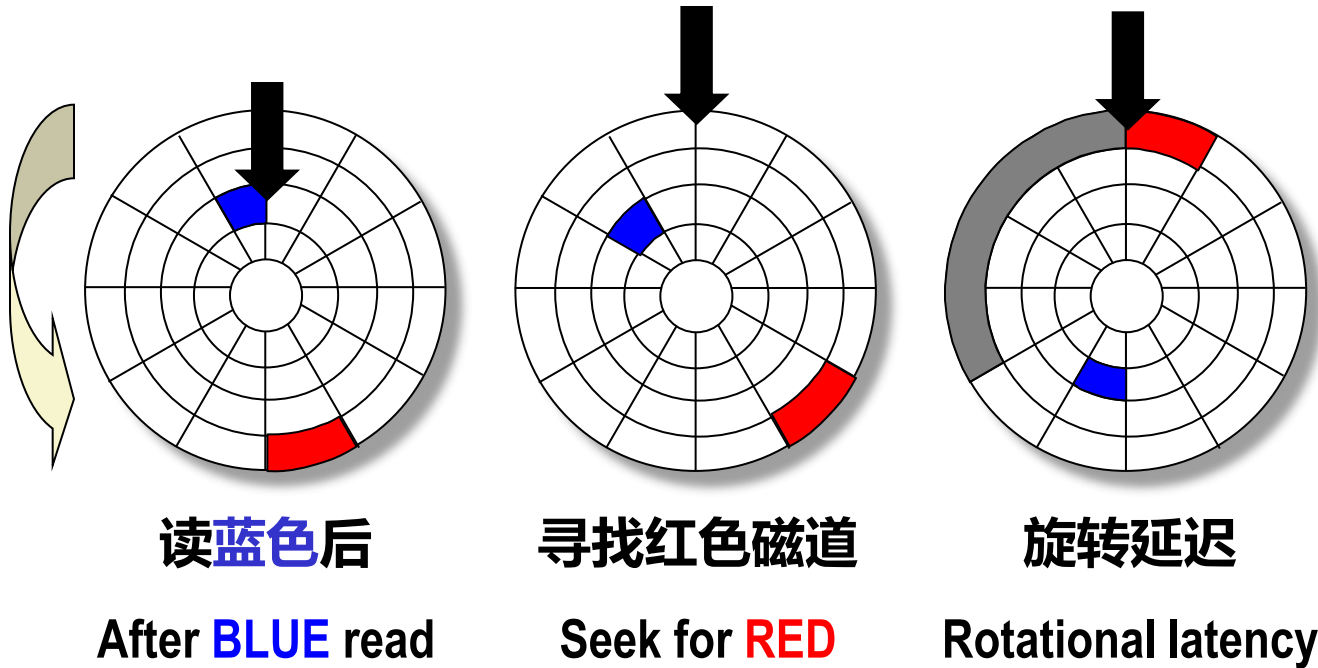
寻找红色磁道

Seek for RED

寻找红色磁道

Seek to red's track

# 磁盘访问-旋转延迟 Disk Access – Rotational Latency

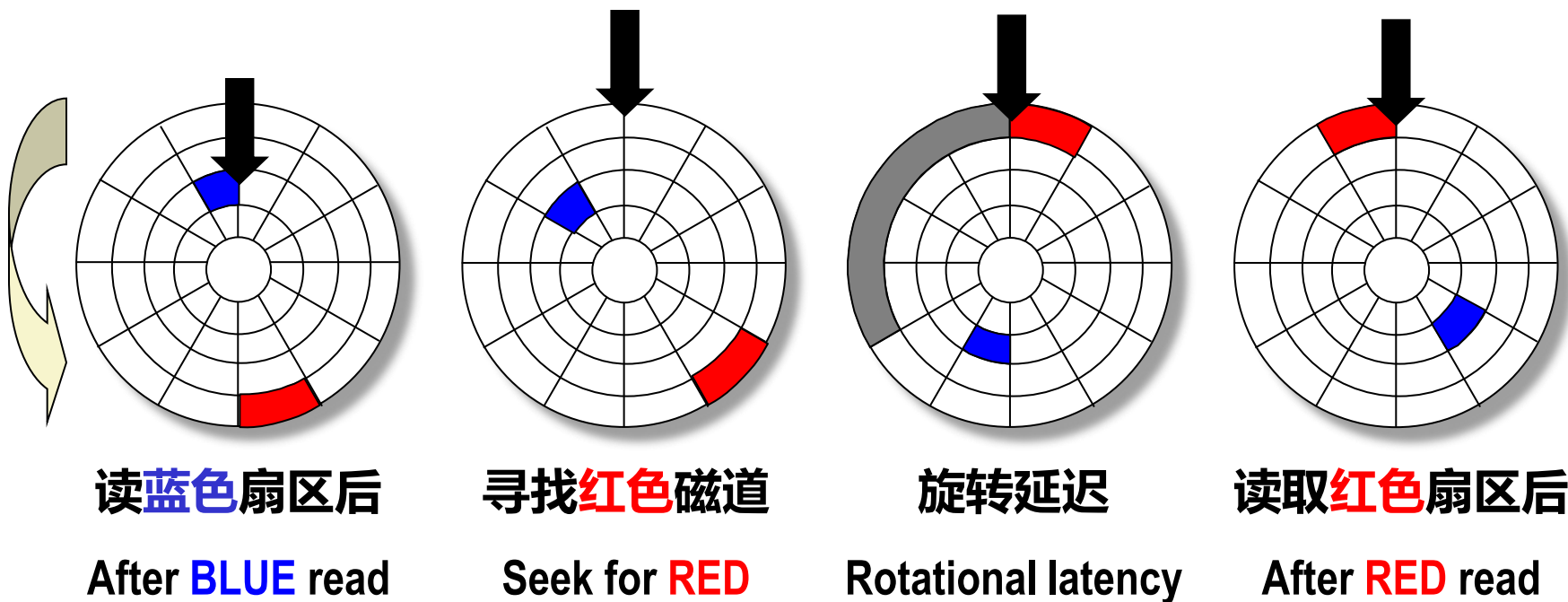


**等待旋转到红色扇区**

**Wait for red sector to rotate around**



# 磁盘访问-读 Disk Access – Read

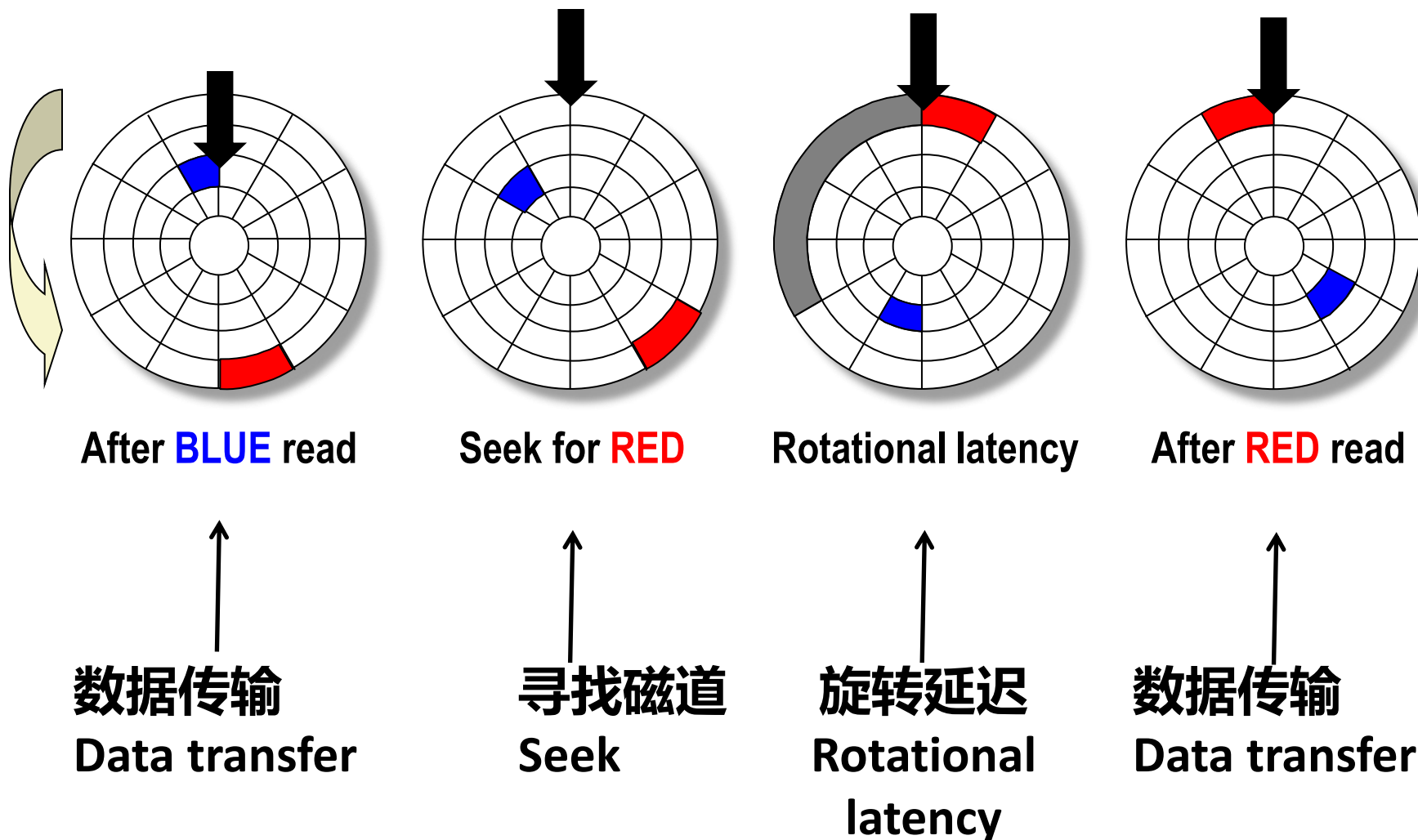


完成红色扇区读取  
Complete read of red



# 磁盘访问-服务时间构成

## Disk Access – Service Time Components



# 磁盘访问时间 Disk Access Time



- 访问某个目标扇区平均时间约为：Average time to access some target sector approximated by :
  - $T_{\text{access}} = T_{\text{avg seek}} + T_{\text{avg rotation}} + T_{\text{avg transfer}}$
- **寻道时间 Seek time ( $T_{\text{avg seek}}$ )**
  - 磁头定位到包含目标扇区的柱面所需时间 Time to position heads over cylinder containing target sector.
  - 典型平均寻道时间为3-9ms Typical  $T_{\text{avg seek}}$  is 3—9 ms
- **旋转时间 Rotational latency ( $T_{\text{avg rotation}}$ )**
  - 等待目标扇区第一位通过读/写磁头下面的时间 Time waiting for first bit of target sector to pass under r/w head.
  - 平均旋转时间= $1/2 \times 1/\text{每分钟转数} \times 60\text{秒/分钟}$   $T_{\text{avg rotation}} = 1/2 \times 1/\text{RPMs} \times 60 \text{ sec}/1 \text{ min}$
  - 典型平均旋转时间为每分钟7200转 Typical  $T_{\text{avg rotation}} = 7200 \text{ RPMs}$
- **传输时间 Transfer time ( $T_{\text{avg transfer}}$ )**
  - 读取目标扇区位的时间 Time to read the bits in the target sector.
  - 平均传输时间= $1/\text{每分钟转数} \times 1/(\text{平均每道扇区数}) \times 60\text{秒/分钟}$   $T_{\text{avg transfer}} = 1/\text{RPM} \times 1/(\text{avg \# sectors/track}) \times 60 \text{ secs}/1 \text{ min}.$

# 磁盘访问时间举例 Disk Access Time Example



## ■ 假定： Given:

- 旋转速率 Rotational rate = 7,200 RPM
- 平均寻道时间 Average seek time = 9 ms.
- 每道平均扇区数 Avg # sectors/track = 400.

## ■ 推导： Derived:

- 平均旋转时间  $T_{avg\ rotation} = 1/2 \times (60\ secs/7200\ RPM) \times 1000\ ms/sec = 4\ ms.$
- 平均传输时间  $T_{avg\ transfer} = 60/7200\ RPM \times 1/400\ secs/track \times 1000\ ms/sec = 0.02\ ms$
- 访问时间  $T_{access} = 9\ ms + 4\ ms + 0.02\ ms$

# 磁盘访问时间举例 Disk Access Time Example



## ■ 重要点： Important points:

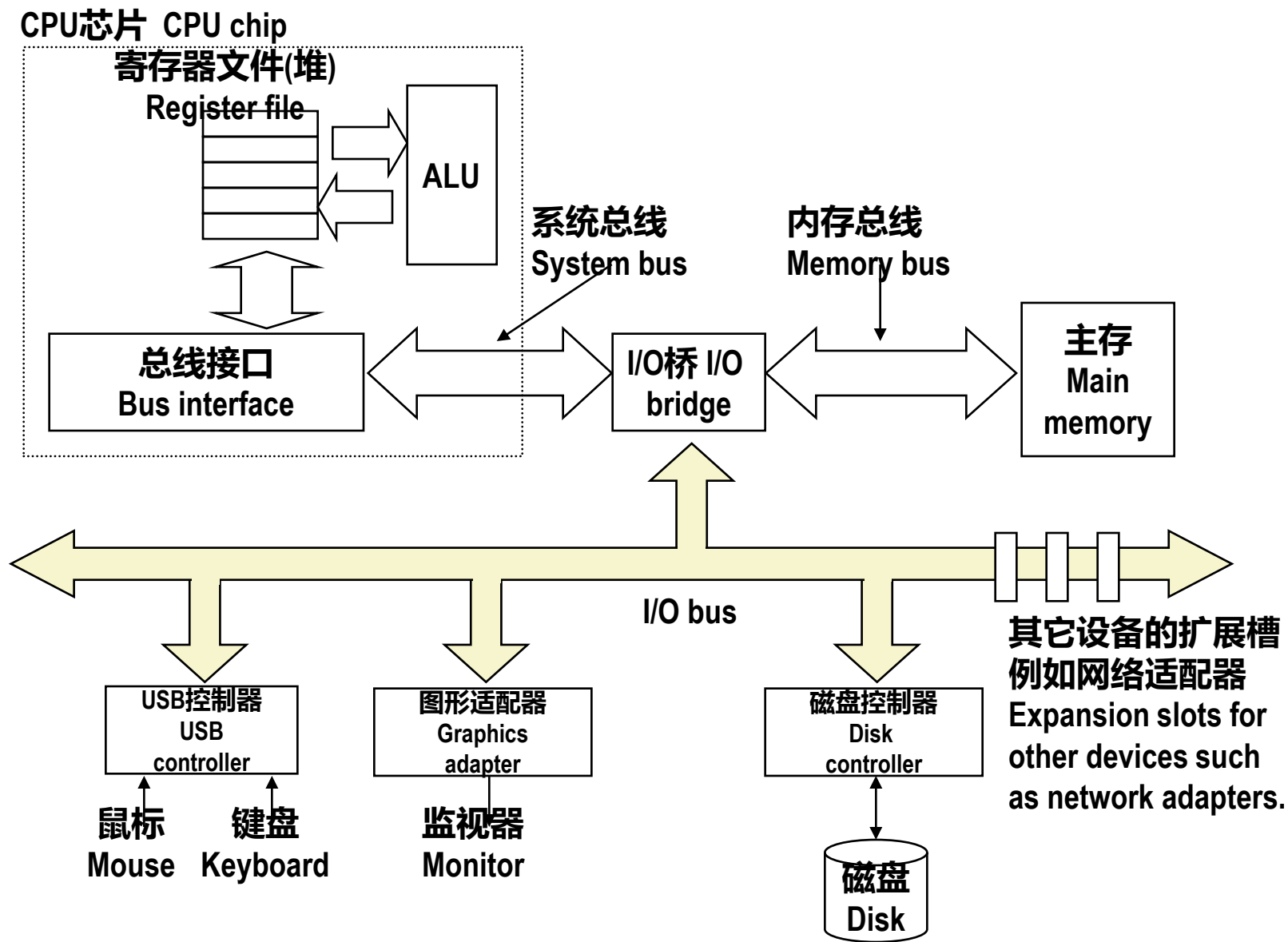
- 访问时间中大部分为寻道时间和旋转延迟 Access time dominated by seek time and rotational latency.
- 访问扇区中第一位时间所需最长，扇区中其它位访问时间很短 First bit in a sector is the most expensive, the rest are free.
- 静态RAM访问时间大约双字为4ns，动态RAM大约为60ns SRAM access time is about 4 ns/doubleword, DRAM about 60 ns
  - 磁盘比静态RAM慢约4万倍 Disk is about 40,000 times slower than SRAM,
  - 比动态RAM慢约2千5百倍 2,500 times slower than DRAM.

# 逻辑磁盘块 Logical Disk Blocks



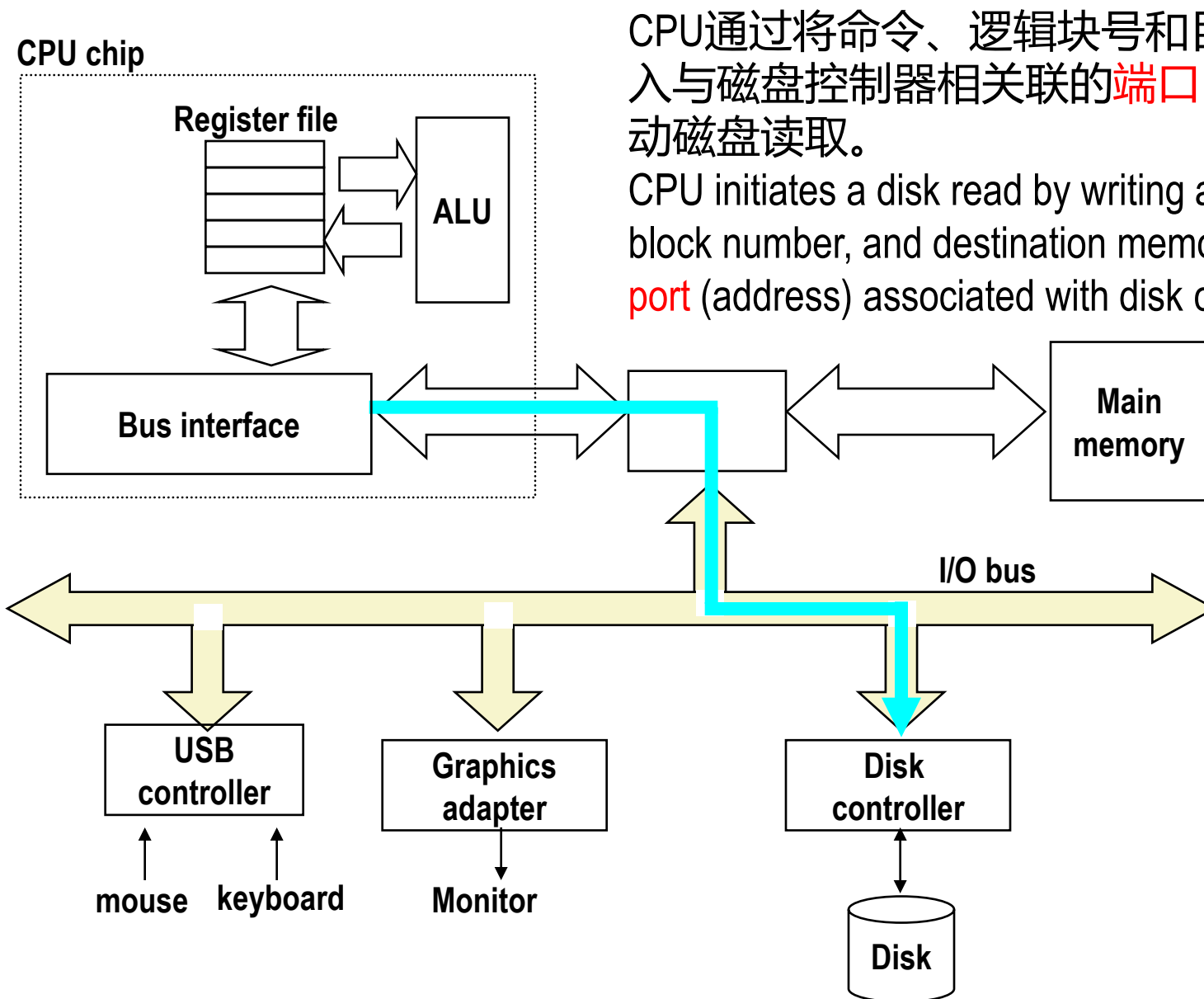
- **现代磁盘提供了复杂扇区结构的更简单抽象视图：Modern disks present a simpler abstract view of the complex sector geometry:**
  - 可用扇区集建模为一系列b大小的**逻辑块** (0、1、2...) The set of available sectors is modeled as a sequence of b-sized **logical blocks** (0, 1, 2, ...)
- **逻辑块和实际（物理）扇区之间的映射 Mapping between logical blocks and actual (physical) sectors**
  - 由称为磁盘控制器的硬件/固件设备维护。 Maintained by hardware/firmware device called disk controller.
  - 将逻辑块请求转换为（表面、磁道、扇区）三元组。 Converts requests for logical blocks into (surface, track, sector) triples.
- **允许控制器为每个区域留出备用柱面 Allows controller to set aside spare cylinders for each zone.**
  - 这也是“格式化容量”和“最大容量”之间存在差异的原因 Accounts for the difference in “formatted capacity” and “maximum capacity”.

# I/O总线 I/O Bus



# 读取磁盘扇区 (1)

## Reading a Disk Sector (1)

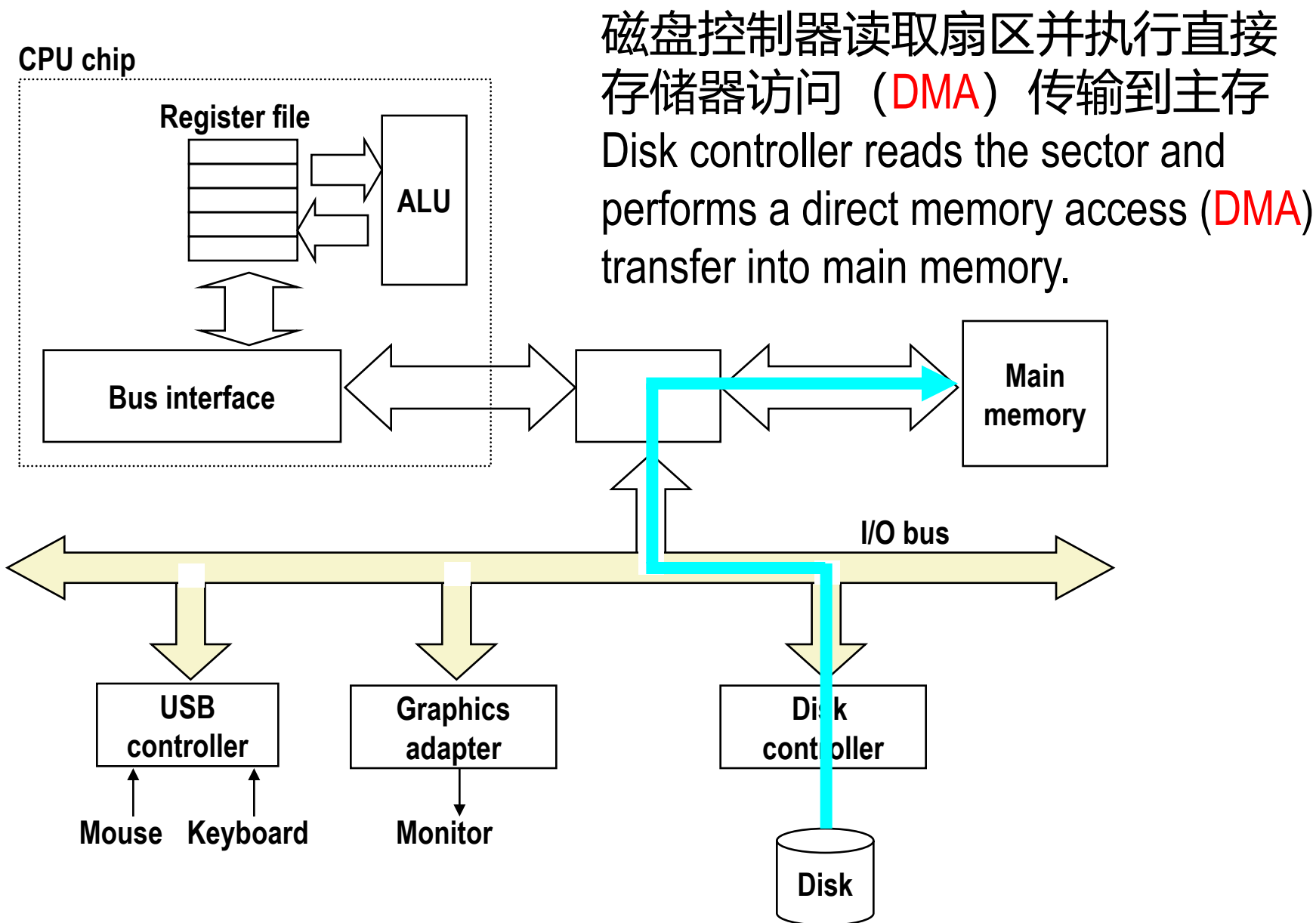


CPU通过将命令、逻辑块号和目标内存地址写入与磁盘控制器相关联的端口（地址）来启动磁盘读取。

CPU initiates a disk read by writing a command, logical block number, and destination memory address to a port (address) associated with disk controller.

# 读取磁盘扇区 (2)

## Reading a Disk Sector (2)





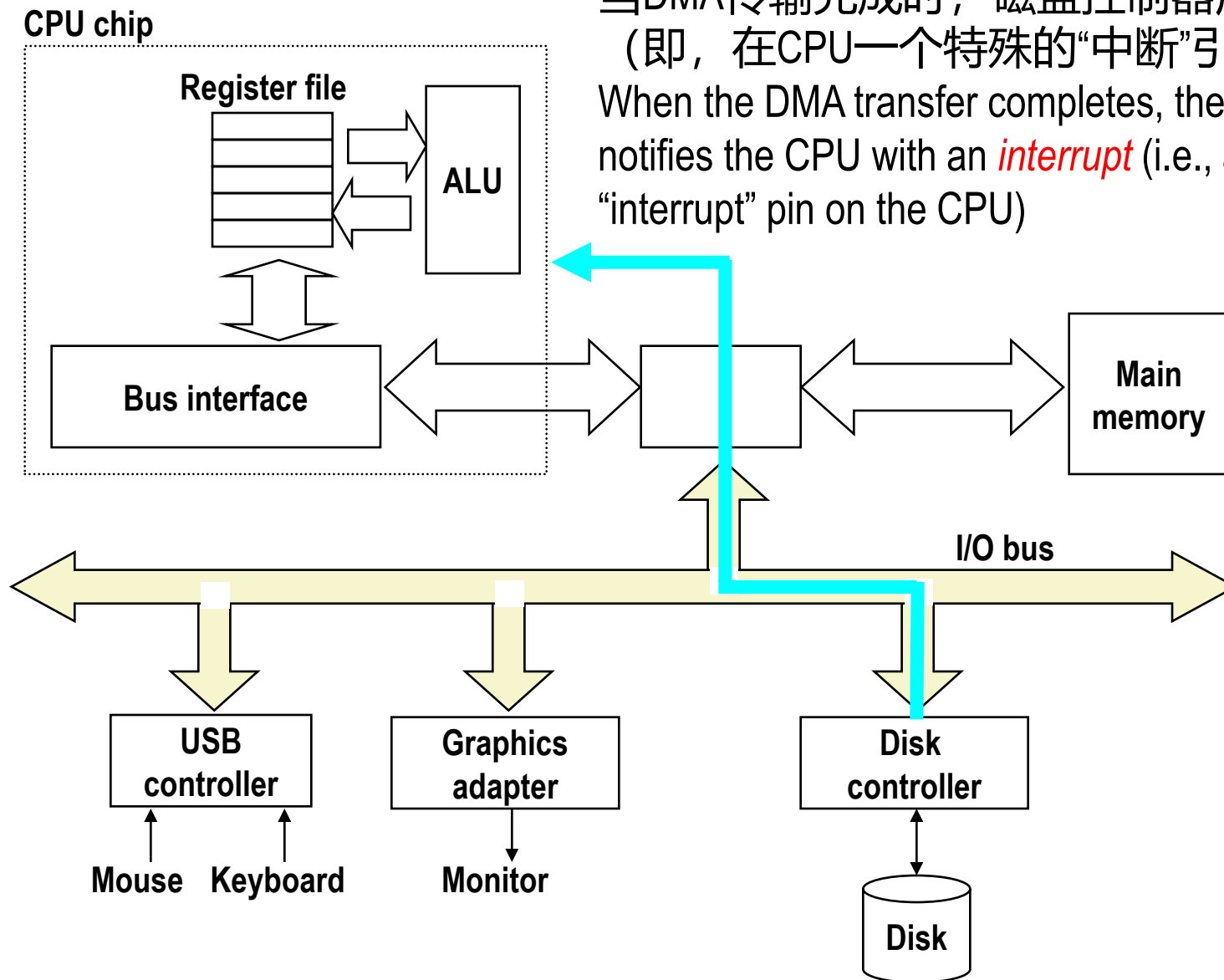
# 读取磁盘扇区 (3)

## Reading a Disk Sector (3)



当DMA传输完成时，磁盘控制器用**中断**通知CPU  
(即，在CPU一个特殊的“中断”引脚产生信号)

When the DMA transfer completes, the disk controller notifies the CPU with an *interrupt* (i.e., asserts a special “interrupt” pin on the CPU)



# 非易失性存储器 Nonvolatile Memories



- **DRAM和SRAM是易失性存储器** DRAM and SRAM are volatile memories
  - 断电时会丢失信息 Lose information if powered off.
- **即使断电，非易失性存储器仍能保持存储的值** Nonvolatile memories retain value even if powered off
  - 只读存储器 (**ROM**)：在生产过程中编程 Read-only memory (**ROM**): programmed during production
  - 电可擦除PROM (**EEPROM**)：电子擦除功能 Electrically erasable PROM (**EEPROM**): electronic erase capability
  - 闪存：EEPROM，具有部分（块级）擦除功能 Flash memory: EEPROMs, with partial (block-level) erase capability
    - 大约100000次擦除后会磨损 Wears out after about 100,000 erasings
  - 3D XPoint (Intel Optane) 和新兴NVM 3D XPoint (Intel Optane) & emerging NVMs
    - 新材料 New materials



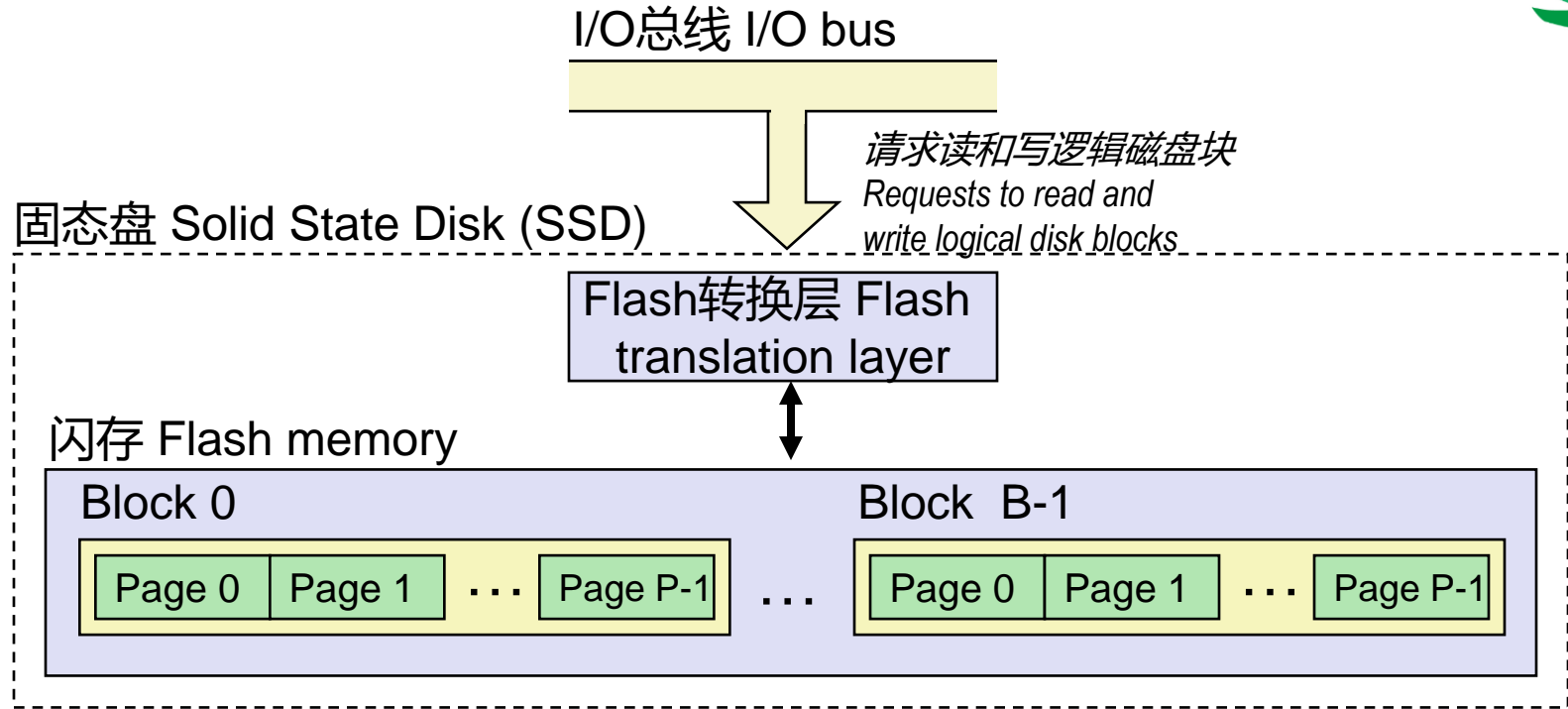
# 非易失性存储器 Nonvolatile Memories



## ■ 非易失性存储器用途 Uses for Nonvolatile Memories

- 在ROM中的固件程序（BIOS、磁盘控制器、网卡、图形加速器、安全子系统...） Firmware programs stored in a ROM (BIOS, controllers for disks, network cards, graphics accelerators, security subsystems,...)
- 固态硬盘（替代旋转磁盘） Solid state disks (replacing rotating disks)
- 磁盘缓存 Disk caches

# 固态硬盘 (SSD) Solid State Disks (SSDs)



- **页大小: 512B至4KB, 块大小: 32至128页** Pages: 512B to 4KB, Blocks: 32 to 128 pages
- **以页面为单位读取/写入数据** Data read/written in units of pages.
- **只有擦除页面块后才能写入页面** Page can be written only after its block has been erased
- **在大约100000次重复写入之后, 一个块会磨损** A block wears out after about 100,000 repeated writes.

# SSD性能特点 SSD Performance Characteristics



## ■ 三星产品测试 Benchmark of Samsung 940 EVO Plus

<https://ssd.userbenchmark.com/SpeedTest/711305/Samsung-SSD-970-EVO-Plus-250GB>

顺序读吞吐量	Sequential read throughput	2,126 MB/s
顺序写吞吐量	Sequential write tput	1,880 MB/s
随机读吞吐量	Random read throughput	140 MB/s
随机写吞吐量	Random write tput	59 MB/s

## ■ 顺序访问比随机访问更快 Sequential access faster than random access

- 存储器层次结构中的公共主题 Common theme in the memory hierarchy

## ■ 随机写入有些慢 Random writes are somewhat slower

- 擦除块需要很长时间 (~1毫秒) Erasing a block takes a long time (~1 ms).
- 修改块页面需要将所有其他页面复制到新块 Modifying a block page requires all other pages to be copied to new block.
- 闪存转换层允许在执行块写入之前积累一系列小写入 Flash translation layer allows accumulating series of small writes before doing block write.

# SSD与旋转磁盘的权衡

## SSD Tradeoffs vs Rotating Disks



### ■ 优势 Advantages

- 无移动部件 → 速度更快、功耗更低、更坚固 No moving parts → faster, less power, more rugged

### ■ 缺点 Disadvantages

- 有可能磨损 Have the potential to wear out
  - 通过闪存转换层中的“损耗均衡逻辑”缓解 Mitigated by “wear leveling logic” in flash translation layer
  - 例如三星940 EVO Plus保证在磨损前每字节可以写入600次 E.g. Samsung 940 EVO Plus guarantees 600 writes/byte of writes before they wear out
  - 控制器迁移数据以最小化磨损程度 Controller migrates data to minimize wear level
- 2019年，每字节的成本大约高出4倍 In 2019, about 4 times more expensive per byte
  - 而且，相对成本将继续下降 And, relative cost will keep dropping

# SSD与旋转磁盘的权衡

## SSD Tradeoffs vs Rotating Disks



### ■ 应用 Applications

- MP3播放器、智能手机、笔记本电脑 MP3 players, smart phones, laptops
- 在台式机和服务器中越来越常见 Increasingly common in desktops and servers

# 小结 Summary



- CPU、内存和大容量存储之间的速度差距继续扩大 The speed gap between CPU, memory and mass storage continues to widen.
- 编写良好的程序具有一种称为**局部性**的特性 Well-written programs exhibit a property called *locality*.
- 基于缓存的内存层次结构通过利用局部性缩小了差距 Memory hierarchies based on *caching* close the gap by exploiting locality.
- 闪存的进步超过了所有其他内存和存储技术（DRAM、SRAM、磁盘） Flash memory progress outpacing all other memory and storage technologies (DRAM, SRAM, magnetic disk)
  - 能够三维堆叠单元 Able to stack cells in three dimensions



# 补充幻灯片 Supplemental slides



# 存储发展趋势 Storage Trends



## SRAM

Metric	1985	1990	1995	2000	2005	2010	2015	2015:1985
\$/MB	2,900	320	256	100	75	60	25	116
access (ns)	150	35	15	3	2	1.5	1.3	115

## DRAM

Metric	1985	1990	1995	2000	2005	2010	2015	2015:1985
\$/MB	880	100	30	1	0.1	0.06	0.02	44,000
access (ns)	200	100	70	60	50	40	20	10
typical size (MB)	0.256	4	16	64	2,000	8,000	16,000	62,500

## Disk

Metric	1985	1990	1995	2000	2005	2010	2015	2015:1985
\$/GB	100,000	8,000	300	10	5	0.3	0.03	3,333,333
access (ms)	75	28	10	8	5	3	3	25
typical size (GB)	0.01	0.16	1	20	160	1,500	3,000	300,000

# CPU时钟频率

## CPU Clock Rates

计算机历史中的拐点，当设计师撞上“功率墙”时

Inflection point in computer history when designers hit the “Power Wall”



	1985	1990	1995	2003	2005	2010	2015	2015:1985
CPU	80286	80386	Pentium	P-4	Core 2	Core i7(n)	Core i7(h)	
Clock rate (MHz)	6	20	150	3,300	2,000	2,500	3,000	500
Cycle time (ns)	166	50	6	0.30	0.50	0.4	0.33	500
Cores	1	1	1	1	2	4	4	4
Effective cycle time (ns)	166	50	6	0.30	0.25	0.10	0.08	2,075

(n) Nehalem processor  
(h) Haswell processor